

# Intel Node Manager Compliant System Power Management and Protection IC with PMBus

Check for Samples: [LM25066I](#), [LM25066IA](#)

## FEATURES

- Fully Node Manager 2.0 and 2.5 Compliant with I2C/SMBus interface and PMBus™ compliant command structure
- Input voltage range: 2.9V to 17V
- Programmable 25mV or 46mV current limit threshold
- Read\_EIN accurately measures true input power via simultaneous sampling
- Configurable circuit breaker protection for hard shorts
- Configurable under- and over-voltage lockouts with hysteresis
- Real time monitoring of  $V_{IN}$ ,  $V_{OUT}$ ,  $I_{IN}$ ,  $P_{IN}$ ,  $V_{AUX}$  with 12-bit resolution and 1 kHz sampling rate
- Current measurement accuracy:  $\pm 1\%$  (LM25066IA) and Power measurement accuracy:  $\pm 2.0\%$  (LM25066IA) over temperature
- Averaging of  $V_{IN}$ ,  $I_{IN}$ ,  $P_{IN}$ , and  $V_{OUT}$  over programmable interval ranging from 0.001 to 4 seconds
- Programmable WARN and FAULT thresholds with SMBA notification
- Blackbox capture of telemetry measurements and device status triggered by WARN or FAULT condition
- 24-lead WQFN package

## DESCRIPTION

While the LM25066I/A is functionally similar to the LM25066/A, the LM25066I/A is fully compliant to Intel Node Manager 2.0, 2.5 and adds the READ\_EIN energy accumulator feature. The LM25066I/A combines a high-performance hot-swap controller with a PMBus 1.2™ compliant SMBus/I<sup>2</sup>C interface to accurately measure, control and protect the electrical operating conditions of critical systems. The LM25066I/A continuously supplies real-time power, voltage, current, temperature, and fault data to the system management host via the SMBus interface.

The LM25066I/A control block includes a unique hot-swap architecture that provides current and power limiting to protect sensitive circuitry even during the most stressful conditions. A fast-acting circuit breaker prevents damage in the event of a short circuit on the output. The input under-voltage, over-voltage hysteresis, insertion delay time and fault detection time are all configurable. A temperature monitoring block on the LM25066I/A interfaces with a low-cost external diode for continuous temperature assessment of the external MOSFET or other thermal sensitive components. The POWER GOOD output provides a fast alert when the input and/or output voltages are outside their programmed range. Accurate power readings are accomplished by using the READ\_EIN command. A black box (Telemetry/Fault Snapshot) function captures and stores telemetry data and device status in the event of a warning or a fault.

## APPLICATIONS

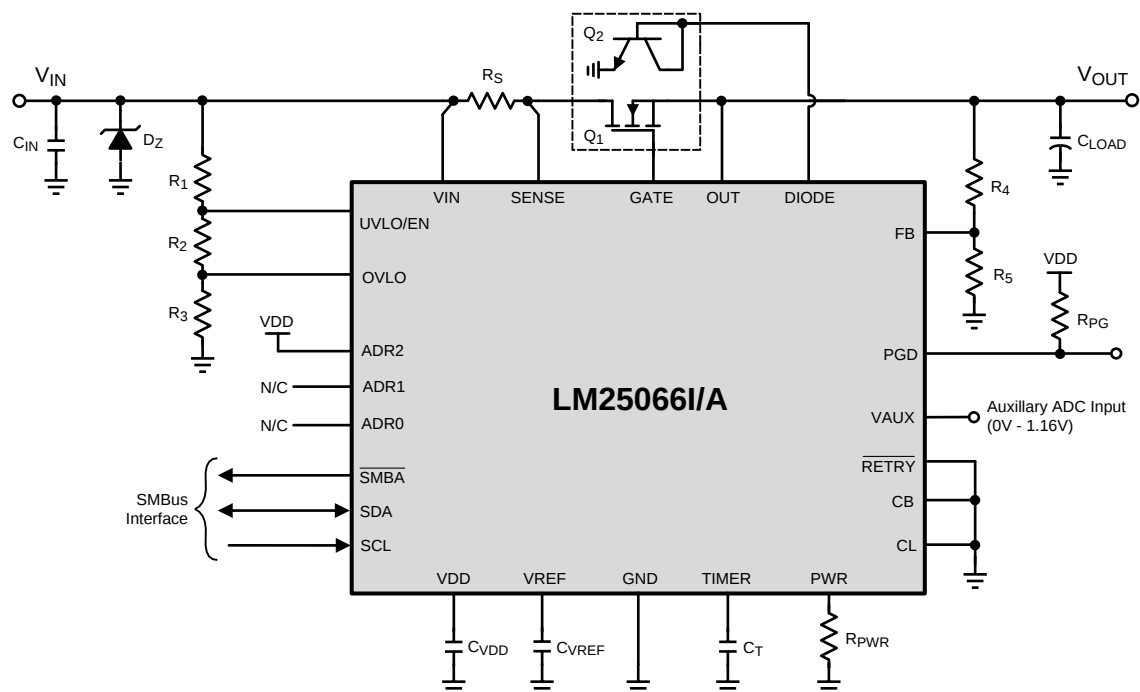
- Server backplane systems
- Basestation power distribution systems
- Solid state circuit breaker (eFuse)



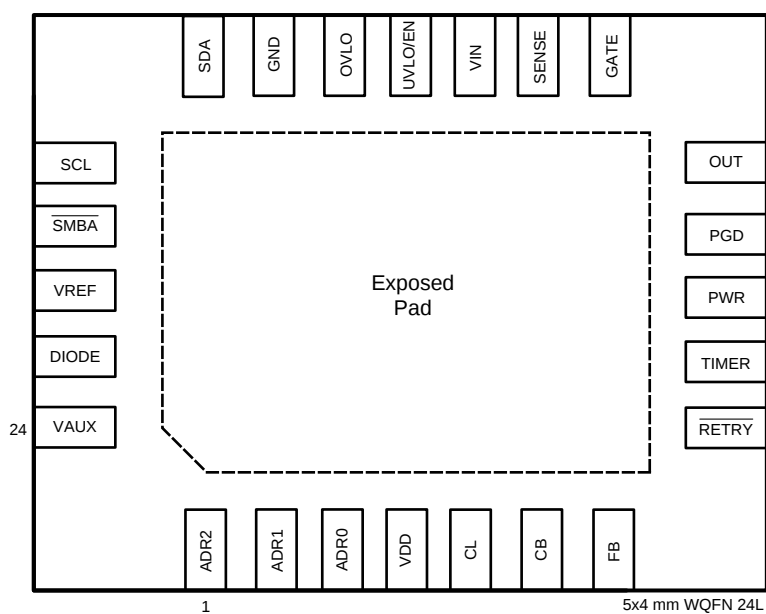
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## Typical Application Schematic



### Connection Diagram



Solder exposed pad to ground.

**Top View**  
**WQFN-24**

### Pin Descriptions

| Pin No. | Name                      | Description                   | Applications Information                                                                                                                                                                                                                                                                                                 |
|---------|---------------------------|-------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Pad     | Exposed Pad               | Exposed pad of WQFN package   | No internal electrical connection. Solder to the ground plane to reduce thermal resistance.                                                                                                                                                                                                                              |
| 1       | ADR2                      | SMBUS address line 2          | 3 - state address line. Should be connected to GND, VDD, or left floating.                                                                                                                                                                                                                                               |
| 2       | ADR1                      | SMBUS address line 1          | 3 - state address line. Should be connected to GND, VDD, or left floating.                                                                                                                                                                                                                                               |
| 3       | ADR0                      | SMBUS address line 0          | 3 - state address line. Should be connected to GND, VDD, or left floating.                                                                                                                                                                                                                                               |
| 4       | VDD                       | Internal sub-regulator output | Internally sub-regulated 4.5V bias supply. Connect a 1 $\mu$ F capacitor on this pin to ground for bypassing.                                                                                                                                                                                                            |
| 5       | CL                        | Current limit range           | Connect this pin to GND to set the nominal over-current threshold at 25mV. Connecting CL to VDD will set the over-current threshold to be 46mV.                                                                                                                                                                          |
| 6       | CB                        | Circuit breaker range         | This pin sets the circuit breaker protection point in relation to the over-current trip point. When connected to GND, this pin will set the circuit breaker point to be 1.8 times the over-current threshold. Connecting this pin to VDD sets the circuit breaker trip point to be 3.6 times the over-current threshold. |
| 7       | FB                        | Power Good feedback           | An external resistor divider from OUT sets the output voltage at which the PGD pin switches. The threshold at the pin is 1.167V. An internal 24 $\mu$ A current source provides hysteresis.                                                                                                                              |
| 8       | $\overline{\text{RETRY}}$ | Fault retry input             | This pin configures the power up fault retry behavior. When this pin is grounded, the device will continually try to engage power during a fault. If the pin is connected to VDD, the device will latch off during a fault.                                                                                              |
| 9       | TIMER                     | Timing capacitor              | An external capacitor connected to this pin sets the insertion time delay, fault timeout period and restart timing.                                                                                                                                                                                                      |
| 10      | PWR                       | Power limit set               | An external resistor connected to this pin, in conjunction with the current sense resistor ( $R_S$ ), sets the maximum power dissipation allowed in the external series pass MOSFET.                                                                                                                                     |
| 11      | PGD                       | Power Good indicator          | An open drain output. This output is high when the voltage at the FB pin is above 1.167V and the input supply is within its under-voltage and over-voltage thresholds. Connect via a pullup resistor to the output rail (external MOSFET source) or any other voltage to be monitored.                                   |
| 12      | OUT                       | Output feedback               | Connect to the output rail (external MOSFET source). Internally used to determine the MOSFET $V_{DS}$ voltage for power limiting, and to monitor the output voltage.                                                                                                                                                     |
| 13      | GATE                      | Gate drive output             | Connect to the external MOSFET's gate.                                                                                                                                                                                                                                                                                   |
| 14      | SENSE                     | Current sense input           | The voltage across the current sense resistor ( $R_S$ ) is measured from VIN to this pin. If the voltage across $R_S$ reaches over-current threshold, the load current is limited and the fault timer activates.                                                                                                         |
| 15      | VIN                       | Positive supply input         | A small ceramic bypass capacitor close to this pin is recommended to suppress transients which occur when the load current is switched off.                                                                                                                                                                              |
| 16      | UVLO/EN                   | Under-voltage lockout         | An external resistor divider from the system input voltage sets the under-voltage turn-on threshold. An internal 23 $\mu$ A current source provides hysteresis. The enable threshold at the pin is 1.16V. This pin can also be used for remote shutdown control.                                                         |
| 17      | OVLO                      | Over-voltage lockout          | An external resistor divider from the system input voltage sets the over-voltage turn-off threshold. An internal 23 $\mu$ A current source provides hysteresis. The disable threshold at the pin is 1.16V.                                                                                                               |
| 18      | GND                       | Circuit ground                |                                                                                                                                                                                                                                                                                                                          |
| 19      | SDA                       | SMBus data pin                | Data pin for SMBus.                                                                                                                                                                                                                                                                                                      |
| 20      | SCL                       | SMBus clock                   | Clock pin for SMBus.                                                                                                                                                                                                                                                                                                     |
| 21      | $\overline{\text{SMBA}}$  | SMBus alert line              | Alert pin for SMBus, active low.                                                                                                                                                                                                                                                                                         |
| 22      | VREF                      | Internal Reference            | Internally generated precision 2.73V reference used for analog to digital conversion. Connect a 1 $\mu$ F capacitor on this pin to ground for bypassing.                                                                                                                                                                 |
| 23      | DIODE                     | External diode                | Connect this to a diode-configured NPN transistor for temperature monitoring.                                                                                                                                                                                                                                            |
| 24      | VAUX                      | Auxiliary voltage input       | Auxiliary pin allows voltage telemetry from an external source. Full scale input of 1.16V.                                                                                                                                                                                                                               |



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**Absolute Maximum Ratings<sup>(1)</sup>**

|                                                                                                                   |                 |
|-------------------------------------------------------------------------------------------------------------------|-----------------|
| VIN, SENSE to GND <sup>(2)</sup>                                                                                  | -0.3V to 24V    |
| GATE, FB, UVLO/EN, OVLO, PGD to GND <sup>(2)</sup>                                                                | -0.3V to 20V    |
| Out to GND                                                                                                        | -1 to 20V       |
| SCL, SDA, $\overline{\text{SMBA}}$ , CL, CB, ADR0, ADR1, ADR2, VDD, VAUX, DIODE, $\overline{\text{RETRY}}$ to GND | -0.3V to 6V     |
| VIN to SENSE                                                                                                      | -0.3V to +0.3V  |
| ESD Rating, Human Body Model <sup>(3)</sup>                                                                       | 2kV             |
| Storage Temperature                                                                                               | -65°C to +150°C |
| Junction Temperature                                                                                              | +150°C          |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional.
- (2) The GATE pin voltage is typically 7.5V above VIN when the LM25066I/A is enabled. Therefore, the Absolute Maximum Rating of 24V for VIN and SENSE apply only when the LM25066I/A is disabled or for a momentary surge to that voltage since the Absolute Maximum Rating for the GATE pin is 20V.
- (3) The human body model is a 100 pF capacitor discharged through a 1.5 k $\Omega$  resistor into each pin.

**Operating Ratings**

|                         |                 |
|-------------------------|-----------------|
| VIN, SENSE, OUT voltage | 2.9V to 17V     |
| VDD                     | 2.9V to 5.5V    |
| Junction Temperature    | -40°C to +125°C |

**Electrical Characteristics**

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  unless otherwise stated. Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply: VIN = 12V. See <sup>(1)</sup> and

| Symbol                         | Parameter                       | Conditions                          | Min          | Typ  | Max          | Unit          |
|--------------------------------|---------------------------------|-------------------------------------|--------------|------|--------------|---------------|
| <b>Input (VIN Pin)</b>         |                                 |                                     |              |      |              |               |
| $I_{IN-EN}$                    | Input Current, enabled          | UVLO = 2V and OVLO = 0.7V           |              | 5.8  | <b>8</b>     | mA            |
| POR                            | Power On Reset threshold at VIN | VIN increasing                      |              | 2.6  | <b>2.8</b>   | V             |
| $POR_{HYS}$                    | $POR_{EN}$ Hysteresis           | VIN decreasing                      |              | 150  |              | mV            |
| <b>VDD Regulator (VDD pin)</b> |                                 |                                     |              |      |              |               |
| $V_{DD}$                       |                                 | $I_{VDD} = 5\text{mA}$ , VIN = 12V  | <b>4.3</b>   | 4.5  | <b>4.7</b>   | V             |
|                                |                                 | $I_{VDD} = 5\text{mA}$ , VIN = 4.5V | <b>3.5</b>   | 3.9  | <b>4.3</b>   | V             |
| $V_{DDILIM}$                   | VDD Current Limit               |                                     | <b>25</b>    | 45   |              | mA            |
| <b>UVLO/EN, OVLO Pins</b>      |                                 |                                     |              |      |              |               |
| $UVLO_{TH}$                    | UVLO threshold                  | $V_{UVLO}$ Falling                  | <b>1.147</b> | 1.16 | <b>1.173</b> | V             |
| $UVLO_{HYS}$                   | UVLO hysteresis current         | UVLO = 1V                           | <b>18</b>    | 23   | <b>28</b>    | $\mu\text{A}$ |
| $UVLO_{DEL}$                   | UVLO delay                      | Delay to GATE high                  |              | 8    |              | $\mu\text{s}$ |
|                                |                                 | Delay to GATE low                   |              | 20   |              |               |
| $UVLO_{BIAS}$                  | UVLO bias current               | UVLO = 3V                           |              |      | <b>1</b>     | $\mu\text{A}$ |
| $OVLO_{TH}$                    | OVLO threshold                  | $V_{OVLO}$ rising                   | <b>1.141</b> | 1.16 | <b>1.185</b> | V             |
| $OVLO_{HYS}$                   | OVLO hysteresis current         | OVLO = 1V                           | <b>-28</b>   | -23  | <b>-18</b>   | $\mu\text{A}$ |
| $OVLO_{DEL}$                   | OVLO delay                      | Delay to GATE high                  |              | 19   |              | $\mu\text{s}$ |
|                                |                                 | Delay to GATE low                   |              | 9    |              |               |
| $OVLO_{BIAS}$                  | OVLO bias current               | OVLO = 1V                           |              |      | <b>1</b>     | $\mu\text{A}$ |
| <b>Power Good (PGD pin)</b>    |                                 |                                     |              |      |              |               |
| $PGD_{VOL}$                    | Output low voltage              | $I_{SINK} = 2\text{mA}$             |              | 25   | <b>60</b>    | mV            |
| $PGD_{IOH}$                    | Off leakage current             | $V_{PGD} = 17\text{V}$              |              |      | <b>1</b>     | $\mu\text{A}$ |
| $PGD_{DELAY}$                  | Power Good Delay                | $V_{FB}$ to $V_{PG}$                |              | 115  |              | ns            |

- (1) Current out of a pin is indicated as a negative value.

## Electrical Characteristics (continued)

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  unless otherwise stated. Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $V_{IN} = 12\text{V}$ . See <sup>(1)</sup> and

| Symbol                   | Parameter                                 | Conditions                                                              | Min   | Typ   | Max  | Unit |
|--------------------------|-------------------------------------------|-------------------------------------------------------------------------|-------|-------|------|------|
| FB Pin                   |                                           |                                                                         |       |       |      |      |
| FB <sub>TH</sub>         | FB Threshold                              | V <sub>FB</sub> rising                                                  | 1.141 | 1.167 | 1.19 | V    |
| FB <sub>HYS</sub>        | FB Hysteresis Current                     |                                                                         | -31   | -24   | -18  | μA   |
| FB <sub>LEAK</sub>       | Off Leakage Current                       | V <sub>FB</sub> = 1V                                                    |       |       | 1    | μA   |
| Power Limit (PWR Pin)    |                                           |                                                                         |       |       |      |      |
| PWR <sub>LIM</sub>       | Power limit sense voltage (VIN-SENSE)     | SENSE-OUT = 12V, R <sub>PWR</sub> = 25 kΩ                               | 9     | 12.5  | 15   | mV   |
| I <sub>PWR</sub>         | PWR pin current                           | V <sub>PWR</sub> = 2.5V                                                 |       | -10   |      | μA   |
| R <sub>SAT(PWR)</sub>    | PWR pin impedance when disabled           | UVLO = 0.7V                                                             |       | 180   |      | Ω    |
| Gate Control (GATE Pin)  |                                           |                                                                         |       |       |      |      |
| I <sub>GATE</sub>        | Source current                            | Normal operation                                                        | -28   | -22   | -16  | μA   |
|                          | Fault Sink current                        | UVLO = 1V                                                               | 1.5   | 2     | 2.5  | mA   |
|                          | POR Circuit Breaker sink current          | VIN - SENSE = 150 mV or VIN < R <sub>POR</sub> , V <sub>GATE</sub> = 5V | 105   | 190   | 275  | mA   |
| V <sub>GATE</sub>        | Gate output voltage in normal operation   | GATE voltage with respect to ground                                     | 17    | 18.8  | 20.3 | V    |
| OUT Pin                  |                                           |                                                                         |       |       |      |      |
| I <sub>OUT-EN</sub>      | OUT bias current, enabled                 | OUT = VIN, normal operation                                             |       | 16    |      | μA   |
| I <sub>OUT-DIS</sub>     | OUT bias current, disabled <sup>(2)</sup> | Disabled, OUT = 0V, SENSE = VIN                                         |       | -12   |      | μA   |
| Current Limit            |                                           |                                                                         |       |       |      |      |
| V <sub>CL</sub>          | Threshold voltage                         | CL = GND                                                                | 22.5  | 25    | 27.5 | mV   |
|                          |                                           | CL = GND, T <sub>j</sub> = 10°C to 85°C                                 | 23    | 25    | 27   |      |
|                          |                                           | CL = VDD                                                                | 41    | 46    | 52   |      |
| t <sub>CL</sub>          | Response time                             | VIN-SENSE stepped from 0 mV to 80 mV                                    |       | 1.2   |      | μs   |
| I <sub>SENSE</sub>       | SENSE input current                       | Enabled, SENSE = OUT                                                    |       | 33    |      | μA   |
|                          |                                           | Disabled, OUT = 0V                                                      |       | 46    |      |      |
|                          |                                           | Enabled, OUT = 0V                                                       |       | 45    |      |      |
| Circuit Breaker          |                                           |                                                                         |       |       |      |      |
| V <sub>CB</sub>          | Threshold voltage x 1.8                   | VIN - SENSE, CL = GND, CB = GND                                         | 35    | 45    | 55   | mV   |
|                          | CB:CL Ratio                               | CB = GND                                                                | 1.6   | 1.8   | 2    |      |
| V <sub>CB</sub>          | Threshold voltage x 3.6                   | VIN - SENSE, CL = GND, CB = VDD                                         | 70    | 90    | 110  | mV   |
|                          | CB:CL Ratio                               | CB = VDD                                                                | 3.1   | 3.6   | 4    |      |
| t <sub>CB</sub>          | Response time                             | VIN - SENSE stepped from 0 mV to 150 mV, time to GATE low, no load      |       | 0.6   | 1.2  | μs   |
| Timer (TIMER pin)        |                                           |                                                                         |       |       |      |      |
| V <sub>TMRH</sub>        | Upper threshold                           |                                                                         | 1.54  | 1.7   | 1.85 | V    |
| V <sub>TMRL</sub>        | Lower threshold                           | Restart cycles                                                          | 0.85  | 1.0   | 1.07 | V    |
|                          |                                           | End of 8 <sup>th</sup> cycle                                            |       | 0.3   |      | V    |
|                          |                                           | Re-enable threshold                                                     |       | 0.3   |      | V    |
| I <sub>TIMER</sub>       | Insertion time current                    | TIMER pin = 2V                                                          | -8    | -5.5  | -3   | μA   |
|                          | Sink current, end of insertion time       |                                                                         | 1.4   | 1.9   | 2.4  | mA   |
|                          | Fault detection current                   |                                                                         | -120  | -90   | -60  | μA   |
|                          | Fault sink current                        |                                                                         |       | 2.8   |      | μA   |
| DC <sub>FAULT</sub>      | Fault Restart Duty Cycle                  |                                                                         |       | 0.67  |      | %    |
| t <sub>FAULT_DELAY</sub> | Fault to GATE low delay                   | TIMER pin reaches the upper threshold                                   |       | 17    |      | μs   |

(2) OUT bias current (disabled) due to leakage current through an internal 0.9 M $\Omega$  resistance from SENSE to VOUT.

## Electrical Characteristics (continued)

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  unless otherwise stated. Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $V_{IN} = 12\text{V}$ . See <sup>(1)</sup> and

| Symbol                    | Parameter                      | Conditions         | Min          | Typ   | Max          | Unit          |
|---------------------------|--------------------------------|--------------------|--------------|-------|--------------|---------------|
| <b>Internal Reference</b> |                                |                    |              |       |              |               |
| $V_{REF}$                 | Reference Voltage              |                    | <b>2.703</b> | 2.73  | <b>2.757</b> | V             |
| <b>ADC and MUX</b>        |                                |                    |              |       |              |               |
|                           | Resolution                     |                    |              | 12    |              | Bits          |
| INL                       | Integral Non-Linearity         | ADC only           |              | +/-1  |              | LSB           |
| $t_{ACQUIRE}$             | Acquisition + Conversion Time  | Any channel        |              | 100   |              | $\mu\text{s}$ |
| $t_{RR}$                  | Acquisition Round Robin Time   | Cycle all channels |              | 1     |              | ms            |
| $I_{IN\_FSR}$             | Current input full scale range | CL = GND           |              | 30.2  |              | mV            |
|                           |                                | CL = VDD           |              | 60.4  |              | mV            |
| $I_{IN\_LSB}$             | Current input LSB              | CL = GND           |              | 7.32  |              | $\mu\text{V}$ |
|                           |                                | CL = VDD           |              | 14.64 |              | $\mu\text{V}$ |
| $VAUX\_FSR$               | VAUX input full scale range    |                    |              | 1.16  |              | V             |
| $VAUX\_LSB$               | VAUX input LSB                 |                    |              | 283.2 |              | $\mu\text{V}$ |
| $V_{IN\_FSR}$             | Input voltage full scale range |                    |              | 18.7  |              | V             |
| $V_{IN\_LSB}$             | Input voltage LSB              |                    |              | 4.54  |              | mV            |

## Electrical Characteristics (continued)

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  unless otherwise stated. Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $V_{IN} = 12\text{V}$ . See <sup>(1)</sup> and

| Symbol                                              | Parameter                                 | Conditions                                                                                                   | Min         | Typ  | Max         | Unit               |
|-----------------------------------------------------|-------------------------------------------|--------------------------------------------------------------------------------------------------------------|-------------|------|-------------|--------------------|
| <b>Telemetry Accuracy LM25066IA</b>                 |                                           |                                                                                                              |             |      |             |                    |
| $I_{IN\_ACC}$                                       | Input Current Accuracy                    | $V_{IN} - \text{SENSE} = 25\text{mV}$ , $CL = \text{GND}$<br>$T_J = 10^\circ\text{C}$ to $85^\circ\text{C}$  | <b>-1</b>   |      | <b>+1</b>   | %                  |
|                                                     |                                           | $V_{IN} - \text{SENSE} = 25\text{mV}$ , $CL = \text{GND}$                                                    | <b>-1.2</b> |      | <b>+1</b>   |                    |
|                                                     |                                           | $V_{IN} - \text{SENSE} = 50\text{mV}$ , $CL = \text{VDD}$                                                    | <b>-1.8</b> |      | <b>+1.8</b> |                    |
|                                                     |                                           | $V_{IN} - \text{SENSE} = 5\text{mV}$ , $CL = \text{GND}$<br>$T_J = 10^\circ\text{C}$ to $85^\circ\text{C}$   | <b>-5</b>   |      | <b>+5</b>   |                    |
| $V_{ACC}$                                           | $V_{AUX}$ , $V_{IN}$ , $V_{OUT}$ Accuracy | $V_{IN}$ , $V_{OUT} = 12\text{V}$<br>$V_{AUX} = 1\text{V}$<br>$T_J = 10^\circ\text{C}$ to $85^\circ\text{C}$ | <b>-1</b>   |      | <b>+1</b>   | %                  |
|                                                     |                                           | $V_{IN}$ , $V_{OUT} = 12\text{V}$<br>$V_{AUX} = 1\text{V}$                                                   | <b>-1</b>   |      | <b>+1.2</b> |                    |
| $P_{IN\_ACC}$                                       | Input Power Accuracy                      | $V_{IN} = 12\text{V}$ , $V_{IN} - \text{SENSE} = 25\text{mV}$ ,<br>$CL = \text{GND}$                         | <b>-2.0</b> |      | <b>+2.0</b> | %                  |
| <b>Telemetry Accuracy LM25066I</b>                  |                                           |                                                                                                              |             |      |             |                    |
| $I_{IN\_ACC}$                                       | Input Current Accuracy                    | $V_{IN} - \text{SENSE} = 25\text{mV}$ , $CL = \text{GND}$                                                    | <b>-2.7</b> |      | <b>+2.4</b> | %                  |
|                                                     |                                           | $V_{IN} - \text{SENSE} = 25\text{mV}$ , $CL = \text{GND}$<br>$T_J = 10^\circ\text{C}$ to $85^\circ\text{C}$  | <b>-2.4</b> |      | <b>+2.4</b> |                    |
| $V_{ACC}$                                           | $V_{AUX}$ , $V_{IN}$ , $V_{OUT}$ Accuracy | $V_{IN}$ , $V_{OUT} = 12\text{V}$<br>$V_{AUX} = 1\text{V}$                                                   | <b>-1.6</b> |      | <b>+1.4</b> | %                  |
|                                                     |                                           | $V_{IN}$ , $V_{OUT} = 12\text{V}$<br>$V_{AUX} = 1\text{V}$<br>$T_J = 10^\circ\text{C}$ to $85^\circ\text{C}$ | <b>-1.4</b> |      | <b>+1.4</b> |                    |
| $P_{IN\_ACC}$                                       | Input Power Accuracy                      | $V_{IN} = 12\text{V}$ , $V_{IN} - \text{SENSE} = 25\text{mV}$ ,<br>$CL = \text{GND}$                         | <b>-3.0</b> |      | <b>+3.0</b> | %                  |
| <b>Remote Diode Temperature Sensor</b>              |                                           |                                                                                                              |             |      |             |                    |
| $T_{ACC}$                                           | Temperature Accuracy Using Local Diode    | $T_A = 10^\circ\text{C}$ to $85^\circ\text{C}$                                                               |             | 2    | <b>10</b>   | $^\circ\text{C}$   |
|                                                     | Remote Diode Resolution                   |                                                                                                              |             | 9    |             | bits               |
| $I_{DIODE}$                                         | External Diode Current Source             | High level                                                                                                   |             | 250  | <b>300</b>  | $\mu\text{A}$      |
|                                                     |                                           | Low level                                                                                                    |             | 9.4  |             | $\mu\text{A}$      |
|                                                     | Diode Current Ratio                       |                                                                                                              |             | 26   |             |                    |
| <b>PMBus Pin Thresholds (SMBA, SDA, SCL)</b>        |                                           |                                                                                                              |             |      |             |                    |
| $V_{IL}$                                            | Data, Clock Input Low Voltage             |                                                                                                              |             |      | <b>0.8</b>  | V                  |
| $V_{IH}$                                            | Data, Clock Input High Voltage            |                                                                                                              | <b>2.1</b>  |      | <b>5.5</b>  | V                  |
| $V_{OL}$                                            | Data Output Low Voltage                   | $I_{PULLUP} = 4\text{mA}$                                                                                    | <b>0</b>    |      | <b>0.4</b>  | V                  |
| $I_{LEAK}$                                          | Input Leakage Current                     | $\text{SDA}$ , $\text{SMBA}$ , $\text{SCL} = 5\text{V}$                                                      |             |      | <b>1</b>    | $\mu\text{A}$      |
| $CL$                                                | Pin Capacitance                           | $\text{SDA}$ , $\text{SCL}$                                                                                  |             | 5    |             | pF                 |
| <b>Configuration Pin Thresholds (CB, CL, RETRY)</b> |                                           |                                                                                                              |             |      |             |                    |
| $V_{IH}$                                            | Threshold Voltage                         |                                                                                                              | <b>3</b>    |      |             | V                  |
| $I_{LEAK}$                                          | Input Leakage Current                     | $CL$ , $CB$ , $\text{RETRY} = 5\text{V}$                                                                     |             |      | <b>1</b>    | mA                 |
| <b>Thermal <sup>(3)</sup></b>                       |                                           |                                                                                                              |             |      |             |                    |
| $\theta_{JA}$                                       | Junction to Ambient                       |                                                                                                              |             | 42.3 |             | $^\circ\text{C/W}$ |
| $\theta_{JC}$                                       | Junction to Case                          |                                                                                                              |             | 9.5  |             | $^\circ\text{C/W}$ |

(3) Junction-to-ambient thermal resistance is highly application and board layout dependent. Specified thermal resistance values for the package specified is based on a 4-layer, 4"x3", 2/1/1/2 oz. Cu board as per JEDEC standards is used.

## Typical Performance Characteristics

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{IN} = 12\text{V}$ . All graphs show junction temperature.

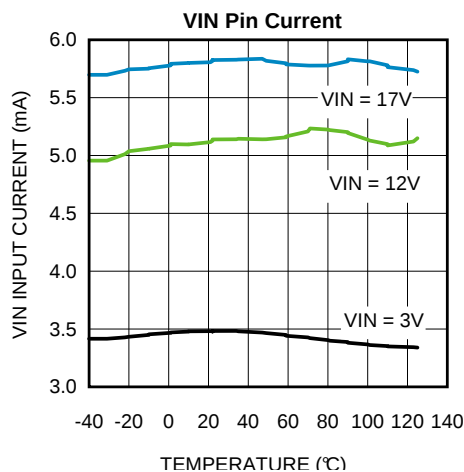


Figure 1.

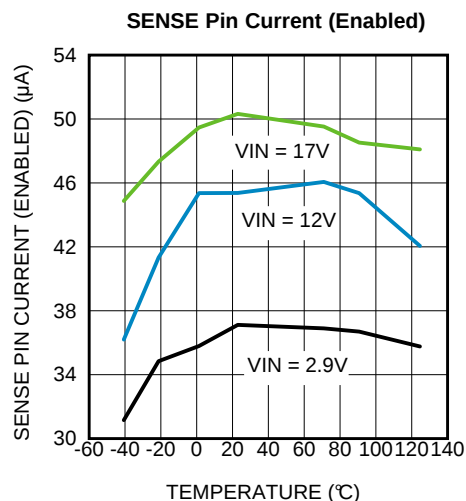


Figure 2.

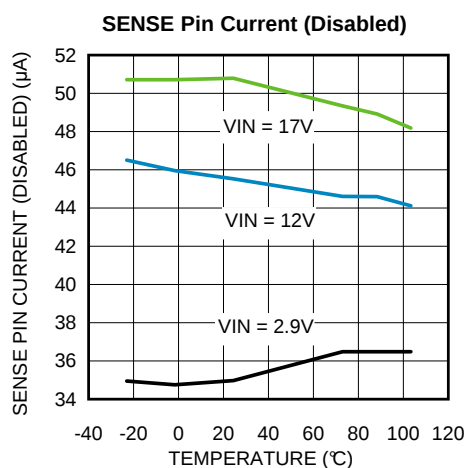


Figure 3.

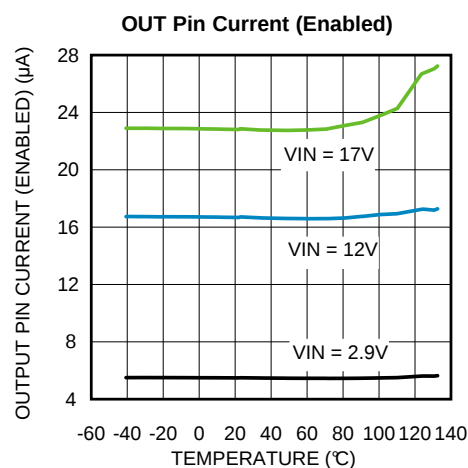


Figure 4.

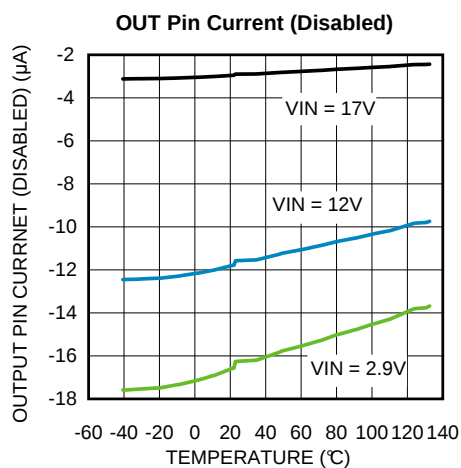


Figure 5.

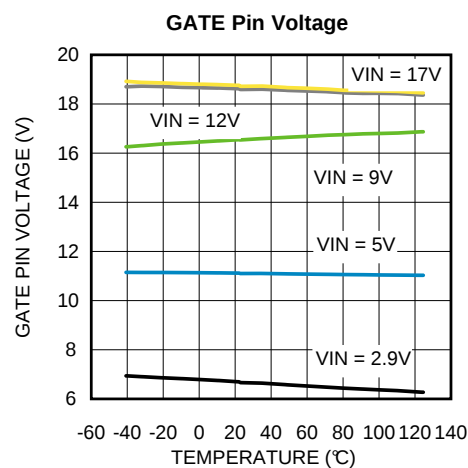


Figure 6.

## Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{IN} = 12\text{V}$ . All graphs show junction temperature.

**GATE Pin Source Current**

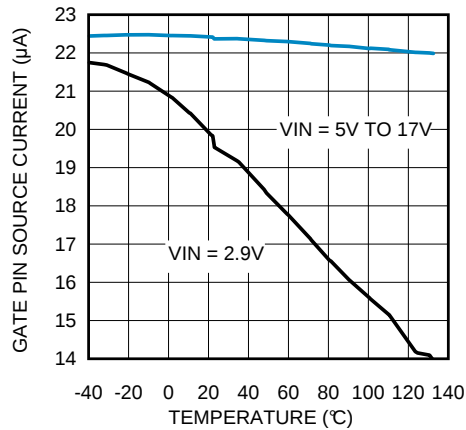


Figure 7.

**Power Limit Threshold**

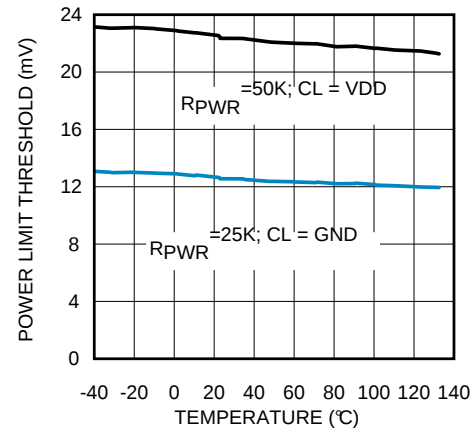


Figure 8.

**PGD Low Voltage**

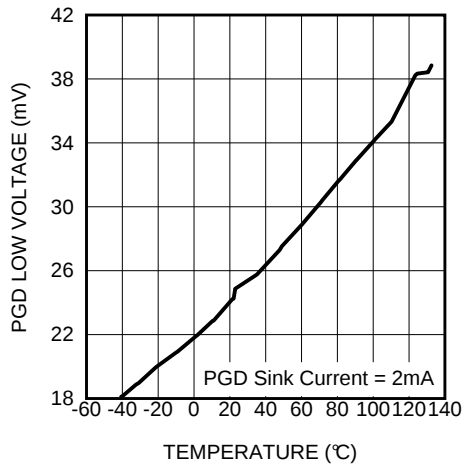


Figure 9.

**UVLO Threshold**

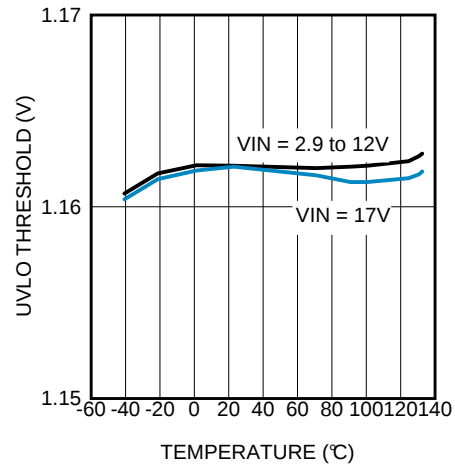


Figure 10.

**UVLO Hysteresis Current**

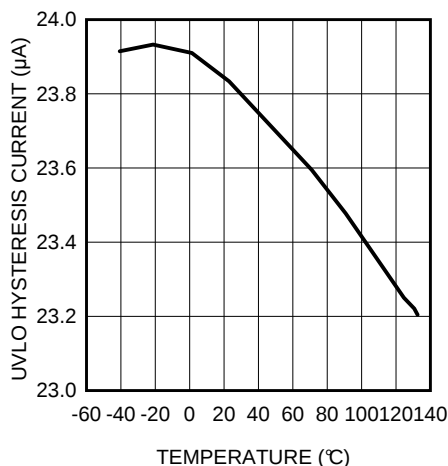


Figure 11.

**FB Threshold**

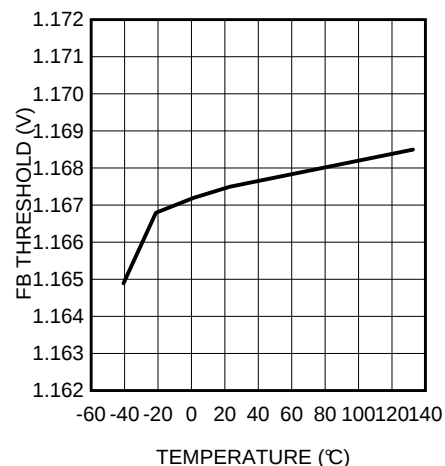


Figure 12.

### Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{IN} = 12\text{V}$ . All graphs show junction temperature.

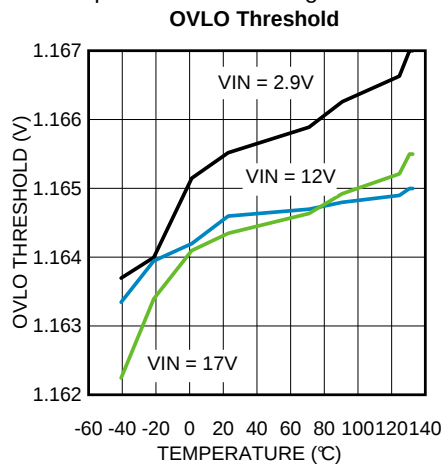


Figure 13.

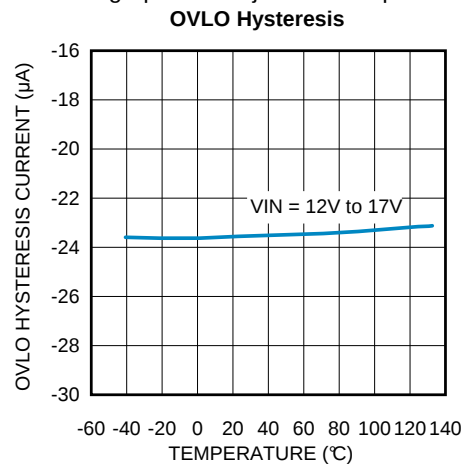


Figure 14.

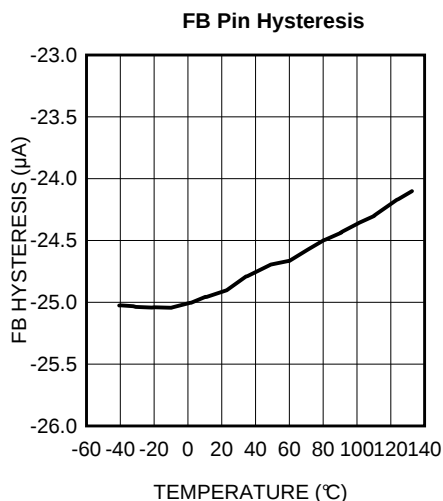


Figure 15.

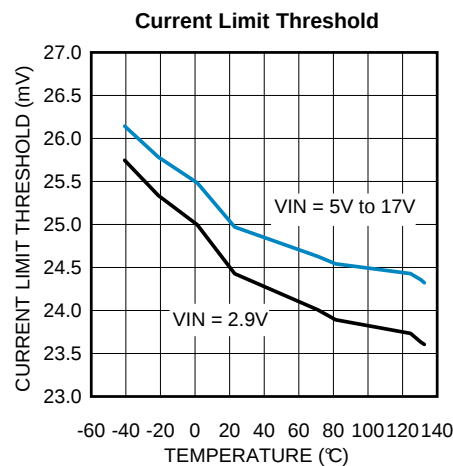


Figure 16.

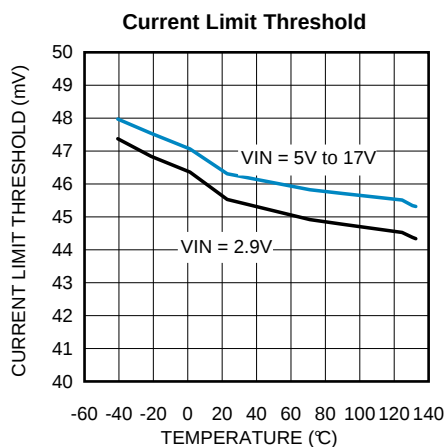


Figure 17.

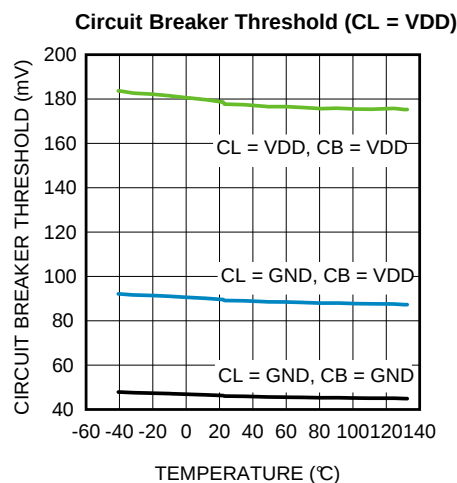


Figure 18.

## Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{IN} = 12\text{V}$ . All graphs show junction temperature.

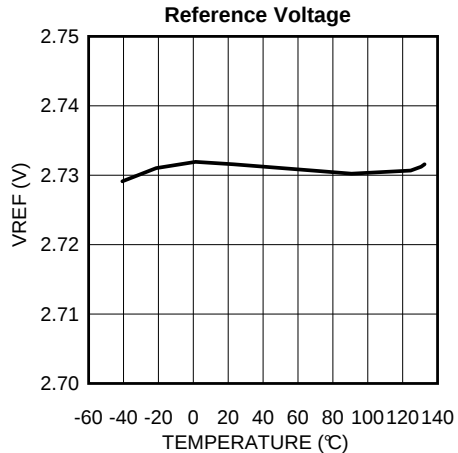


Figure 19.

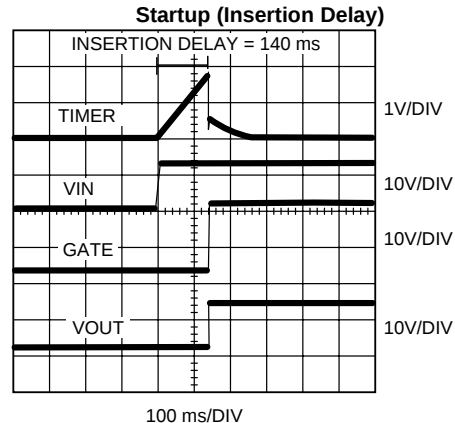


Figure 20.

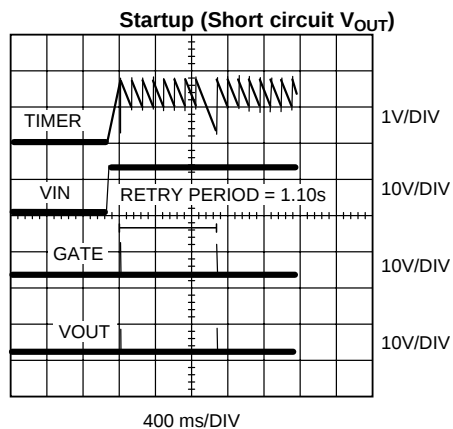


Figure 21.

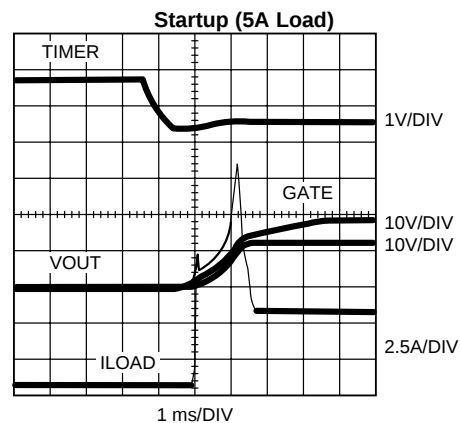


Figure 22.

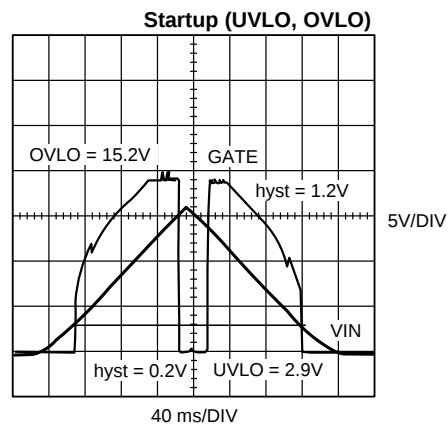


Figure 23.

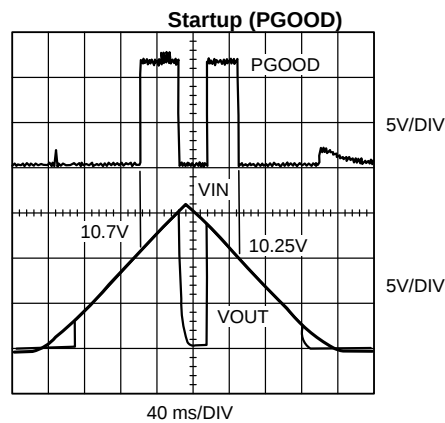


Figure 24.

### Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{IN} = 12\text{V}$ . All graphs show junction temperature.

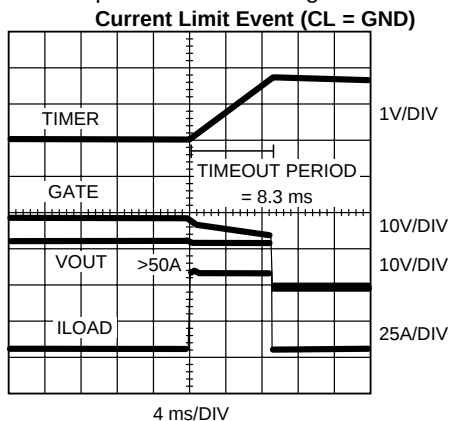


Figure 25.

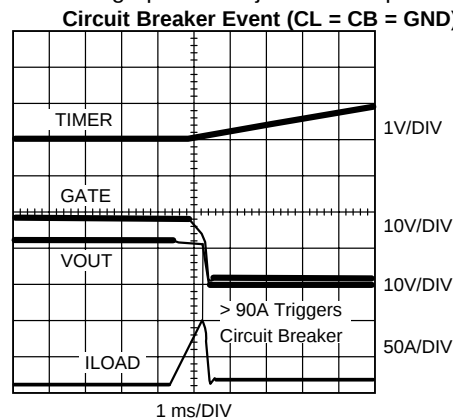


Figure 26.

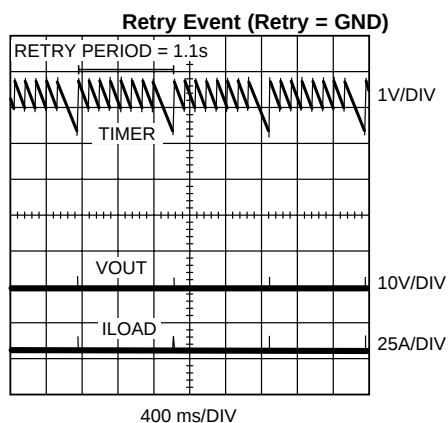


Figure 27.

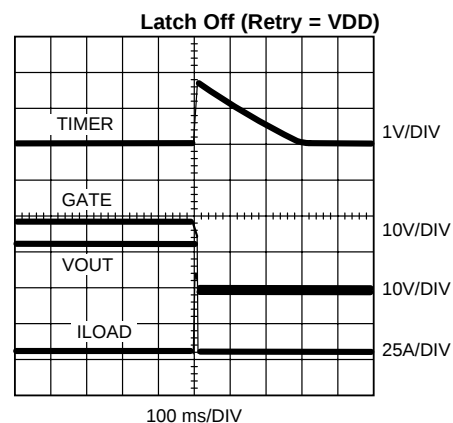


Figure 28.

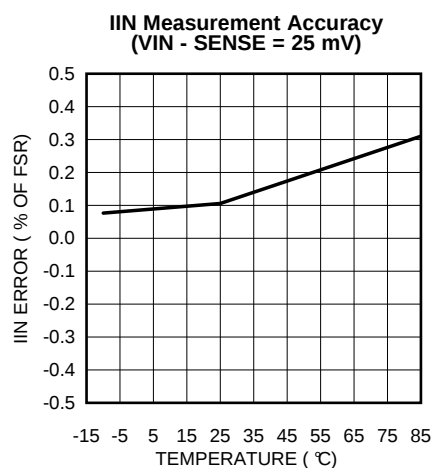


Figure 29.

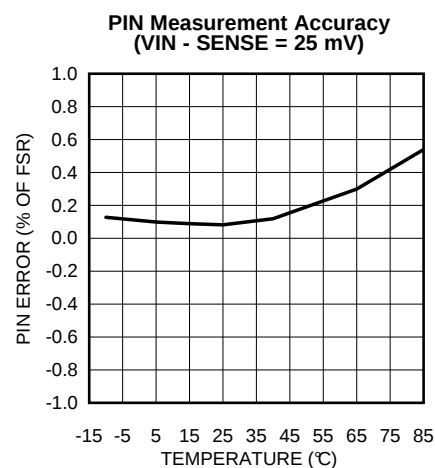
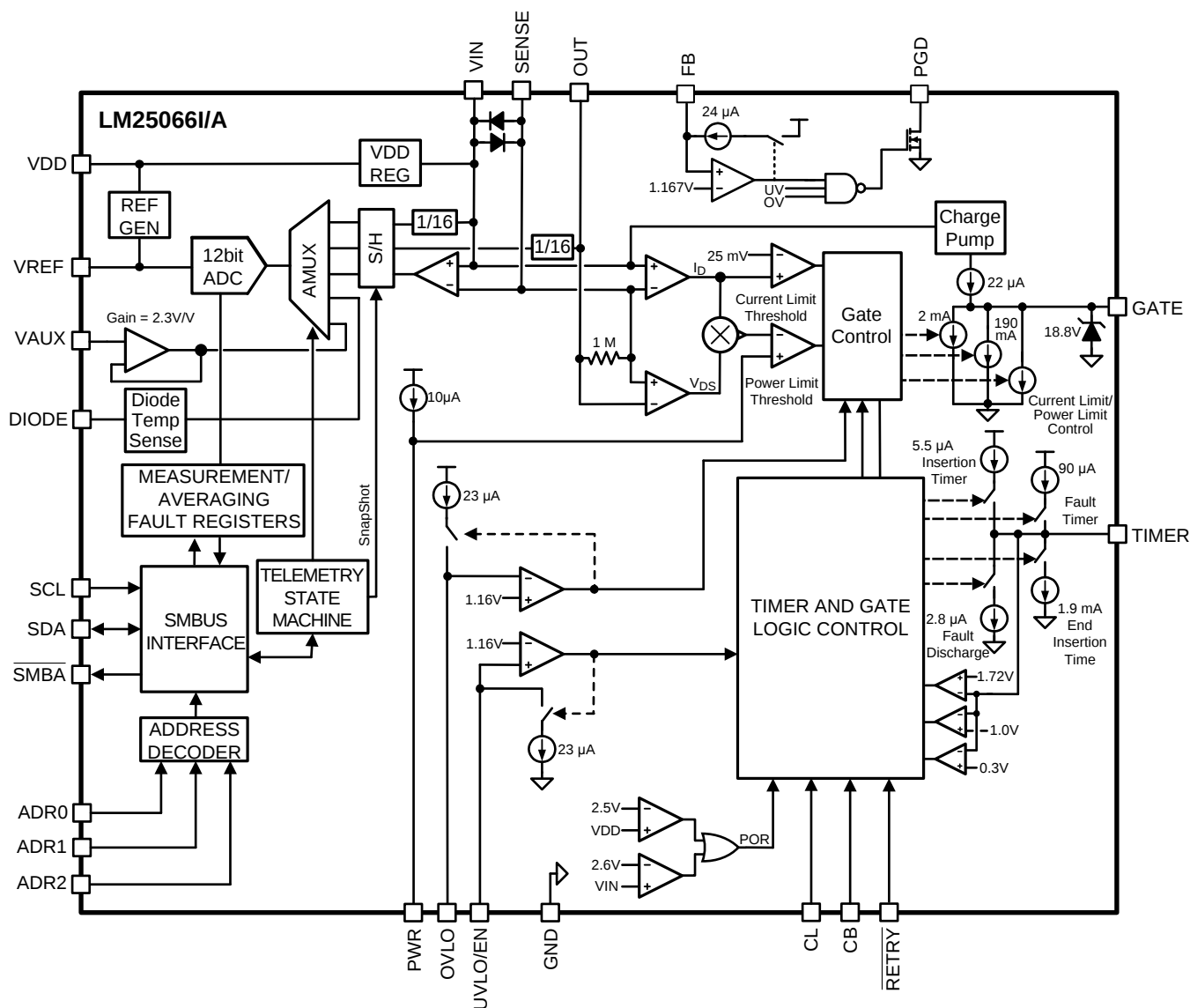


Figure 30.

# BLOCK DIAGRAM



## FUNCTIONAL DESCRIPTION

The inline protection functionality of the LM25066I/A is designed to control the in-rush current to the load upon insertion of a circuit card into a live backplane or other “hot” power source, thereby limiting the voltage sag on the backplane’s supply voltage and the  $dV/dt$  of the voltage applied to the load. Effects on other circuits in the system are minimized, preventing possible unintended resets. A controlled shutdown when the circuit card is removed can also be implemented using the LM25066I/A.

In addition to a programmable current limit, the LM25066I/A monitors and limits the maximum power dissipation in the series pass device to maintain operation within the device Safe Operating Area (SOA). Either current limiting or power limiting for an extended period of time results in the shutdown of the series pass device. In this event, the LM25066I/A can latch off or repetitively retry based on the hardware setting of the RETRY pin. Once started, the number of retries can be set to none, 1, 2, 4, 8, 16, or infinite. The circuit breaker function quickly switches off the series pass device upon detection of a severe over-current condition. Programmable under-voltage lockout (UVLO) and over-voltage lockout (OVLO) circuits shut down the LM25066I/A when the system input voltage is outside the desired operating range.

The telemetry capability of the LM25066I/A provides intelligent monitoring of the input voltage, output voltage, input current, input power, temperature, and an auxiliary input. The LM25066I/A also provides a peak capture of the input power and programmable hardware averaging of the input voltage, current, power, and output voltage. Warning thresholds which trigger the SMBA pin may be programmed for input and output voltage, current, power and temperature via the PMBus interface. Additionally, the LM25066I/A is capable of detecting damage to the external MOSFET,  $Q_1$ .

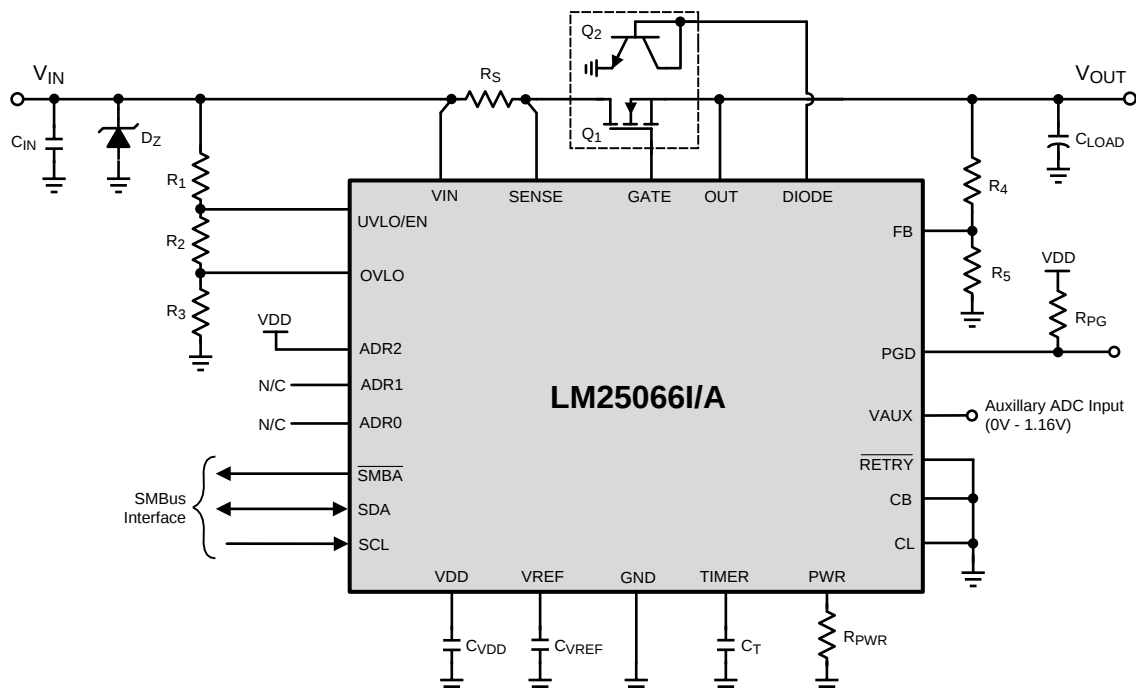


Figure 31. Typical Application Circuit

### Power Up Sequence

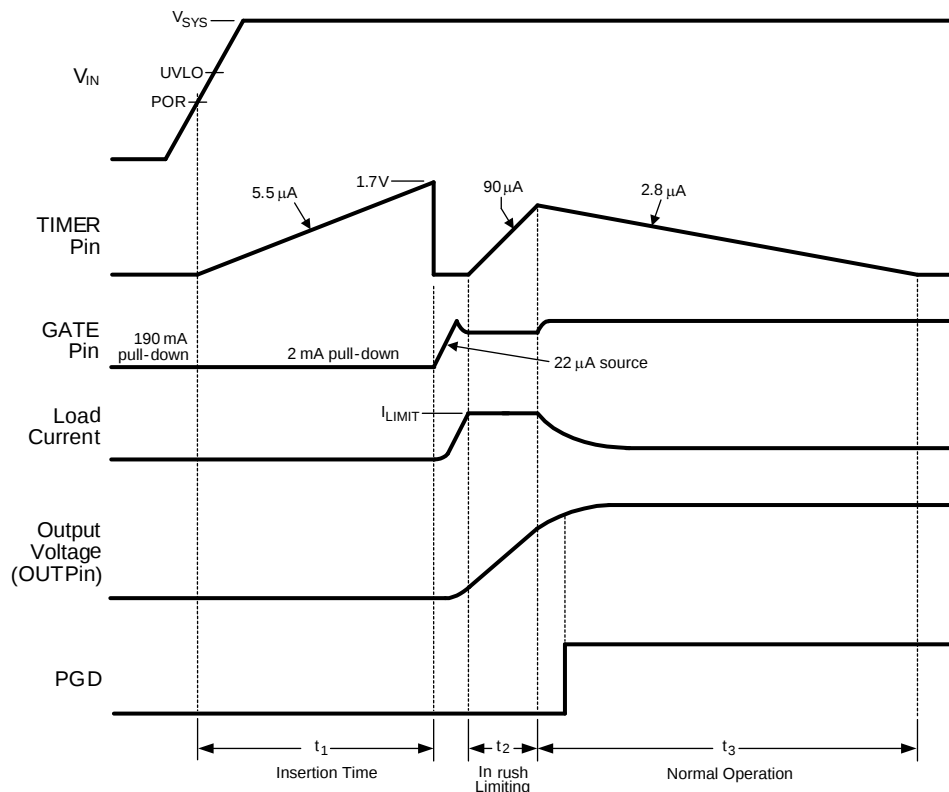
The  $V_{IN}$  operating range of the LM25066I/A is +2.9V to +17V, with transient capability to +24V. Referring to Figure 31 and Figure 32, as the voltage at  $V_{IN}$  initially increases, the external N-channel MOSFET ( $Q_1$ ) is held off by an internal 190 mA pulldown current at the GATE pin. The strong pulldown current at the GATE pin prevents an inadvertent turn-on as the MOSFET’s gate-to-drain (Miller) capacitance is charged. Additionally, the TIMER pin is initially held at ground. When the  $V_{IN}$  voltage reaches the POR threshold, the insertion time begins. During the insertion time, the capacitor at the TIMER pin ( $C_T$ ) is charged by a 5.5  $\mu$ A current source and  $Q_1$  is held off by a 2 mA pulldown current at the GATE pin regardless of the input voltage. The insertion time delay allows ringing and transients at  $V_{IN}$  to settle before  $Q_1$  is enabled. The insertion time ends when the TIMER pin

voltage reaches 1.7V.  $C_T$  is then quickly discharged by an internal 1.9 mA pulldown current. The GATE pin then switches on  $Q_1$  when  $V_{SYS}$ , the input supply voltage, exceeds the UVLO threshold. If  $V_{SYS}$  is above the UVLO threshold at the end of the insertion time,  $Q_1$  switches on at that time. The GATE pin charge pump sources 22  $\mu$ A to charge the gate capacitance of  $Q_1$ . The maximum voltage at the GATE pin with respect to ground is limited by an internal 18.8V zener diode.

As the voltage at the OUT pin increases, the LM25066I/A monitors the drain current and power dissipation of MOSFET  $Q_1$ . Inrush current limiting and/or power limiting circuits actively control the current delivered to the load. During the inrush limiting interval ( $t_2$  in Figure 32), an internal 90  $\mu$ A fault timer current source charges  $C_T$ . If  $Q_1$ 's power dissipation and the input current reduce below their respective limiting thresholds before the TIMER pin reaches 1.7V, the 90  $\mu$ A current source is switched off and  $C_T$  is discharged by the internal 2.8  $\mu$ A current sink ( $t_3$  in Figure 32). The PGD pin switches high when FB exceeds its rising threshold of 1.167V.

If the TIMER pin voltage reaches 1.7V before inrush current limiting or power limiting ceases during  $t_2$ , a fault is declared and  $Q_1$  is turned off. See [Fault Timer and Restart](#) for a complete description of the fault mode.

The LM25066I/A will pull the  $\overline{SMBA}$  pin low after the input voltage has exceeded its POR threshold to indicate that the volatile memory and device settings are in their default state. The CONFIG\_PRESET bit within the STATUS\_MFR\_SPECIFIC register (80h) indicates default configuration of warning thresholds and device operation and will remain set until a CLEAR\_FAULTS command is received.



**Figure 32. Power Up Sequence (Current Limit Only)**

## Gate Control

A charge pump provides the voltage at the GATE pin to enhance the N-Channel MOSFET's gate. During normal operating conditions ( $t_3$  in [Figure 32](#)) the gate of  $Q_1$  is held charged by an internal 22  $\mu\text{A}$  current source. The voltage at the GATE pin (with respect to ground) is limited by an internal 18.8 V zener diode. See the graph "GATE Pin Voltage" shown previously. Since the gate-to-source voltage applied to  $Q_1$  could be as high as 18.8 V during various conditions, a zener diode with the appropriate voltage rating must be added between the GATE and OUT pins if the maximum  $V_{GS}$  rating of the selected MOSFET is less than 18.8 V. The external zener diode must have a forward current rating of at least 190 mA. When the system voltage is initially applied, the GATE pin is held low by a 190 mA pulldown current. This helps prevent an inadvertent turn-on of the MOSFET through its drain-gate capacitance as the applied system voltage increases.

During the insertion time ( $t_1$  in [Figure 32](#)) the GATE pin is held low by a 2 mA pulldown current. This maintains  $Q_1$  in the off-state until the end of  $t_1$ , regardless of the voltage at VIN or UVLO. Following the insertion time ( $t_2$  in [Figure 32](#)), the gate voltage of  $Q_1$  is controlled to keep the current or power dissipation level from exceeding the programmed levels. While in the current or power limiting mode, the TIMER pin capacitor is charging. If the current and power limiting cease before the TIMER pin reaches 1.7V, the TIMER pin capacitor then discharges, and the circuit begins normal operation. If the inrush limiting condition persists such that the TIMER pin reached 1.7V during  $t_2$ , the GATE pin is then pulled low by the 190 mA pulldown current. The GATE pin is then held low until either a power up sequence is initiated ([RETRY](#) pin to VDD), or an automatic retry is attempted ([RETRY](#) pin to GROUND). See [Fault Timer and Restart](#). If the system input voltage falls below the UVLO threshold or rises above the OVLO threshold, the GATE pin is pulled low by the 2 mA pulldown current to switch off  $Q_1$ .

## Current Limit

The current limit threshold is reached when the voltage across the sense resistor  $R_S$  (VIN to SENSE) exceeds the internal voltage limit of 25 mV or 46 mV depending on whether the CL pin is connected to GND or VDD, respectively. In the current limiting condition, the GATE voltage is controlled to limit the current in MOSFET  $Q_1$ . While the current limit circuit is active, the fault timer is active as described in [Fault Timer and Restart](#). If the load current falls below the current limit threshold before the end of the Fault Timeout Period, the LM25066I/A resumes normal operation. If the current limit condition persists for longer than the Fault Timeout Period set by the timer capacitor,  $C_T$ , the IIN\_OC\_FAULT bit in the STATUS\_INPUT (7Ch) register, the INPUT bit in the STATUS\_WORD (79h) register, and the IIN\_OC/PFET\_OP\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register will be toggled high and [SMBA](#) pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register. For proper operation, the  $R_S$  resistor value should be less than 200 m $\Omega$ . Higher values may create instability in the current limit control loop. The current limit threshold pin value may be overridden by setting appropriate bits in the DEVICE\_SETUP register (D9h).

## Circuit Breaker

If the load current increases rapidly (e.g. the load is short circuited), the current in the sense resistor ( $R_S$ ) may exceed the current limit threshold before the current limit control loop is able to respond. If the current exceeds 1.8 or 3.6 times (user settable) the current limit threshold,  $Q_1$  is quickly switched off by the 190 mA pulldown current at the GATE pin, and a Fault Timeout Period begins. When the voltage across  $R_S$  falls below the threshold the 190 mA pulldown current at the GATE pin is switched off and the gate voltage of  $Q_1$  is then determined by the current limit or power limit functions. If the TIMER pin reaches 1.7V before the current limiting or power limiting condition ceases,  $Q_1$  is switched off by the 2 mA pulldown current at the GATE pin as described in [Fault Timer and Restart](#). A circuit breaker event will cause the CIRCUIT BREAKER\_FAULT bit in the STATUS\_MFR\_SPECIFIC (80h) and DIAGNOSTIC\_WORD (E1h) registers to be toggled high and [SMBA](#) pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register. The circuit breaker pin configuration may be overridden by setting appropriate bits in the DEVICE\_SETUP (D9h) register.

## Power Limit

An important feature of the LM25066I/A is the MOSFET power limiting. The Power Limit function can be used to maintain the maximum power dissipation of MOSFET  $Q_1$  within the device SOA rating. The LM25066I/A determines the power dissipation in  $Q_1$  by monitoring its drain-source voltage (SENSE to OUT), and the drain current through  $R_S$  (VIN to SENSE). The product of the current and voltage is compared to the power limit threshold programmed by the resistor at the PWR pin. If the power dissipation reaches the limiting threshold, the GATE voltage is controlled to regulate the current in  $Q_1$ . While the power limiting circuit is active, the fault timer is

active as described in [Fault Timer and Restart](#). If the power limit condition persists for longer than the Fault Timeout Period set by the timer capacitor,  $C_T$ , the IIN\_OC\_FAULT bit in the STATUS\_INPUT (7Ch) register, the INPUT bit in the STATUS\_WORD (79h) register, and the IIN\_OC/PFET\_OP\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register will be toggled high and SMBA pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register.

## Fault Timer and Restart

When the current limit or power limit threshold is reached during turn-on, or as a result of a fault condition, the gate-to-source voltage of  $Q_1$  is controlled to regulate the load current and power dissipation in  $Q_1$ . When either limiting function is active, a 90  $\mu$ A fault timer current source charges the external capacitor ( $C_T$ ) at the TIMER pin as shown in [Figure 32](#) (Fault Timeout Period). If the fault condition subsides during the Fault Timeout Period before the TIMER pin reaches 1.7V, the LM25066I/A returns to the normal operating mode and  $C_T$  is discharged by the 1.9 mA current sink. If the TIMER pin reaches 1.7V during the Fault Timeout Period,  $Q_1$  is switched off by a 2 mA pulldown current at the GATE pin. The subsequent restart procedure then depends on the selected retry configuration.

If the  $\overline{\text{RETRY}}$  pin is high, the LM25066I/A latches the GATE pin low at the end of the Fault Timeout Period.  $C_T$  is then discharged to ground by the 2.8  $\mu$ A fault current sink. The GATE pin is held low by the 2 mA pulldown current until a power up sequence is externally initiated by cycling the input voltage ( $V_{\text{SYS}}$ ), or momentarily pulling the UVLO/EN pin below its threshold with an open-collector or open-drain device as shown in [Figure 33](#). The voltage at the TIMER pin must be <0.3V for the restart procedure to be effective. The TIMER\_LATCHED\_OFF bit in the DIAGNOSTIC\_WORD (E1h) register will remain high while the latched off condition persists.

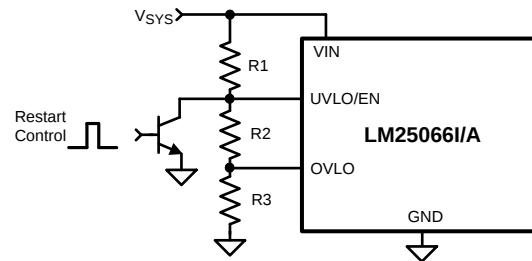


Figure 33. Latched Fault Restart Control

The LM25066I/A provides an automatic restart sequence which consists of the TIMER pin cycling between 1.7V and 1V seven times after the Fault Timeout Period, as shown in [Figure 34](#). The period of each cycle is determined by the 90  $\mu$ A charging current, and the 2.8  $\mu$ A discharge current, and the value of the capacitor  $C_T$ . When the TIMER pin reaches 0.3V during the eighth high-to-low ramp, the 22  $\mu$ A current source at the GATE pin turns on  $Q_1$ . If the fault condition is still present, the Fault Timeout Period and the restart sequence repeat. The  $\overline{\text{RETRY}}$  pin allows selecting no retries or infinite retries. Finer control of the retry behavior can be achieved through the DEVICE\_SETUP (D9h) register. Retry counts of 0, 1, 2, 4, 8, 16 or infinite may be selected by setting the appropriate bits in the DEVICE\_SETUP (D9h) register.

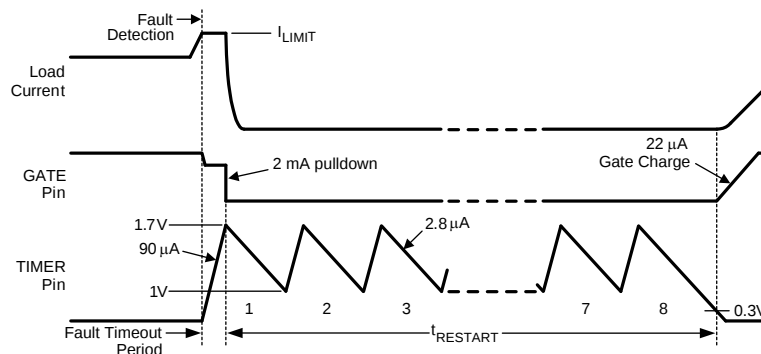


Figure 34. Restart Sequence

## Under-Voltage Lockout (UVLO)

The series pass MOSFET ( $Q_1$ ) is enabled when the input supply voltage ( $V_{SYS}$ ) is within the operating range defined by the programmable under-voltage lockout (UVLO) and over-voltage lockout (OVLO) levels. Typically the UVLO level at  $V_{SYS}$  is set with a resistor divider (R1-R3) as shown in Figure 35. Referring to the Block Diagram when  $V_{SYS}$  is below the UVLO level, the internal 23  $\mu$ A current source at UVLO is enabled, the current source at OVLO is off, and  $Q_1$  is held off by the 2 mA pulldown current at the GATE pin. As  $V_{SYS}$  is increased, raising the voltage at UVLO above its threshold the 23  $\mu$ A current source at UVLO is switched off, increasing the voltage at UVLO, providing hysteresis for this threshold. With the UVLO/EN pin above its threshold,  $Q_1$  is switched on by the 22  $\mu$ A current source at the GATE pin if the insertion time delay has expired.

See Applications Section for a procedure to calculate the values of the threshold setting resistors (R1-R3). The minimum possible UVLO level at  $V_{SYS}$  can be set by connecting the UVLO/EN pin to VIN. In this case,  $Q_1$  is enabled after the insertion time when the voltage at VIN reaches the POR threshold. After power up, an UVLO condition will toggle high the VIN UV FAULT bit in the STATUS\_INPUT (7Ch), the INPUT bit in the STATUS\_WORD register, and the VIN\_UNDERVOLTAGE\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register, and SMBA pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register.

## Over-Voltage Lockout (OVLO)

The series pass MOSFET ( $Q_1$ ) is enabled when the input supply voltage ( $V_{SYS}$ ) is within the operating range defined by the programmable under-voltage lockout (UVLO) and over-voltage lockout (OVLO) levels. If  $V_{SYS}$  raises the OVLO pin voltage above its threshold,  $Q_1$  is switched off by the 2 mA pulldown current at the GATE pin, denying power to the load. When the OVLO pin is above its threshold, the internal 23  $\mu$ A current source at OVLO is switched on, raising the voltage at OVLO to provide threshold hysteresis. When  $V_{SYS}$  is reduced below the OVLO level,  $Q_1$  is re-enabled. An OVLO condition will toggle high the VIN OV FAULT bit in the STATUS\_INPUT (7Ch), the INPUT bit in the STATUS\_WORD register, and the VIN\_OVERVOLTAGE\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register, and the SMBA pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register.

See Applications Section for a procedure to calculate the threshold setting resistor values.

## Shutdown Control

The load current can be remotely switched off by taking the UVLO/EN pin below its threshold with an open collector or open drain device, as shown in Figure 35. Upon releasing the UVLO/EN pin, the LM25066I/A switches on the load current with inrush current and power limiting.

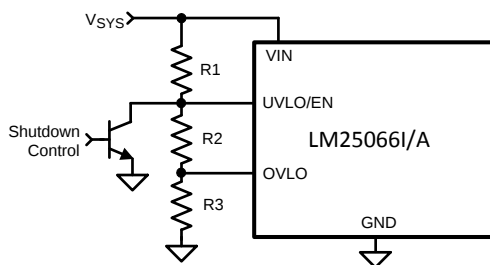


Figure 35. Shutdown Control

## Power Good

The Power Good indicator (PGD) is connected to the drain of an internal N-channel MOSFET capable of sustaining 17V in the off-state, and transients up to 20V. An external pullup resistor is required at PGD to an appropriate voltage to indicate the status to downstream circuitry. The off-state voltage at the PGD pin can be higher or lower than the voltages at VIN and OUT. PGD is switched high when the voltage at the FB pin exceeds the PGD threshold voltage. Typically, the output voltage threshold is set with a resistor divider from output to feedback, although the monitored voltage need not be the output voltage. Any other voltage can be monitored as long as the voltage at the FB pin does not exceed its maximum rating. Referring to the Block Diagram, when the

voltage at the FB pin is below its threshold, the 24  $\mu$ A current source at FB is disabled. As the output voltage increases, taking FB above its threshold, the current source is enabled, sourcing current out of the pin, raising the voltage at FB to provide threshold hysteresis. The PGD output is forced low when either the UVLO/EN pin is below its threshold or the OVLO pin is above its threshold. The status of the PGD pin can be read via the PMBus interface in either the STATUS\_WORD (79h) or DIAGNOSTIC\_WORD (E1h) registers.

## VDD Sub-Regulator

The LM25066I/A contains an internal linear sub-regulator which steps down the input voltage to generate a 4.5V rail used for powering low voltage circuitry. When the input voltage is below 4.5V, VDD will track VIN. For input voltages 3.3V and below, VDD should be tied directly to VIN to avoid the dropout of the sub-regulator. The VDD sub-regulator should be used as the pullup supply for the CL, CB, RETRY, ADR2, ADR1, ADR0 pins if they are to be tied high. It may also be used as the pullup supply for the PGD and the SMBus signals (SDA, SCL, SMBA). The VDD sub-regulator is not designed to drive high currents and should not be loaded with other integrated circuits. The VDD pin is current limited to 45mA in order to protect the LM25066I/A in the event of a short. The sub-regulator requires a bypass capacitance having a value between 1  $\mu$ F and 4.7  $\mu$ F to be placed as close to the VDD pin as the PCB layout allows.

## Remote Temperature Sensing

The LM25066I/A is designed to measure temperature remotely using an MMBT3904 NPN transistor. The base and collector of the MMBT3904 is connected to the DIODE pin and the emitter is grounded. Place the MMBT3904 near the device whose temperature is to be monitored. If the temperature of the hot-swap pass MOSFET, Q<sub>1</sub>, is to be measured, the MMBT3904 should be placed as close to Q<sub>1</sub> as the layout allows. The temperature is measured by means of a change in the diode voltage in response to a step in current supplied by the DIODE pin. The DIODE pin sources a constant 9.4  $\mu$ A but pulses 250  $\mu$ A once every millisecond in order to measure the diode temperature. Care must be taken in the PCB layout to keep the parasitic resistance between the DIODE pin and the MMBT3904 low so as not to degrade the measurement. Additionally, a small 1000 pF bypass capacitor should be placed in parallel with the MMBT3904 to reduce the effects of noise. The temperature can be read using the READ\_TEMPERATURE\_1 PMBus command (8Dh). The default limits of the LM25066I/A will cause SMBA pin to be pulled low if the measured temperature exceeds 125°C and will disable the hot-swap pass MOSFET if the temperature exceeds 150°C. These thresholds can be reprogrammed via the PMBus interface using the OT\_WARN\_LIMIT (51h) and OT\_FAULT\_LIMIT (4Fh) commands. If the temperature measurement and protection capability of the LM25066I/A is not used, the DIODE pin should be grounded.

## Damaged MOSFET Detection

The LM25066I/A is able to detect whether the external MOSFET, Q<sub>1</sub>, is damaged under certain conditions. If the voltage across the sense resistor exceeds 4mV while the GATE voltage is low or the internal logic indicates that the GATE should be low, the EXT\_MOSFET\_SHORTED bit in the STATUS\_MFR\_SPECIFIC (80h) and DIAGNOSTIC\_WORD (E1h) registers will be toggled high and the SMBA pin will be pulled low unless this feature is disabled using the ALERT\_MASK register (D8h). This method effectively determines whether Q<sub>1</sub> is shorted because of damage present between the drain and gate and/or drain and source of the external MOSFET.

## Enabling, Disabling, and Resetting

The output can be disabled at any time during normal operation by either pulling the UVLO/EN pin to below its threshold or the OVLO pin above its threshold, causing the GATE voltage to be forced low with a pulldown strength of 2mA. Toggling the UVLO/EN pin will also reset the LM25066I/A from a latched-off state due to an over-current or over-power limit condition which has caused the maximum allowed number of retries to be exceeded. While the UVLO/EN or OVLO pins can be used to disable the output, they have no effect on the volatile memory or address location of the LM25066I/A. User stored values for address, device operation, and warning and fault levels programmed via the SMBus are preserved while the LM25066I/A is powered regardless of the state of the UVLO/EN and OVLO pins. The output may also be enabled or disabled by writing 80h or 0h to the OPERATION (03h) register. To re-enable after a fault, the fault condition should be cleared and the OPERATION (03h) register should be written to 0h and then 80h.

The SMBus address of the LM25066I/A is captured based on the states of the ADR0, ADR1, and ADR2 pins (GND, NC, VDD) during turn-on and is latched into a volatile register once VDD has exceeded its POR threshold of 2.6V. Reassigning or postponing the address capture is accomplished by holding the VREF pin to ground. Pulling the VREF pin low will also reset the logic and erase the volatile memory of the LM25066I/A. Once released, the VREF pin will charge up to its final value and the address will be latched into a volatile register once the voltage at the VREF exceeds 2.4V.

## APPLICATIONS SECTION

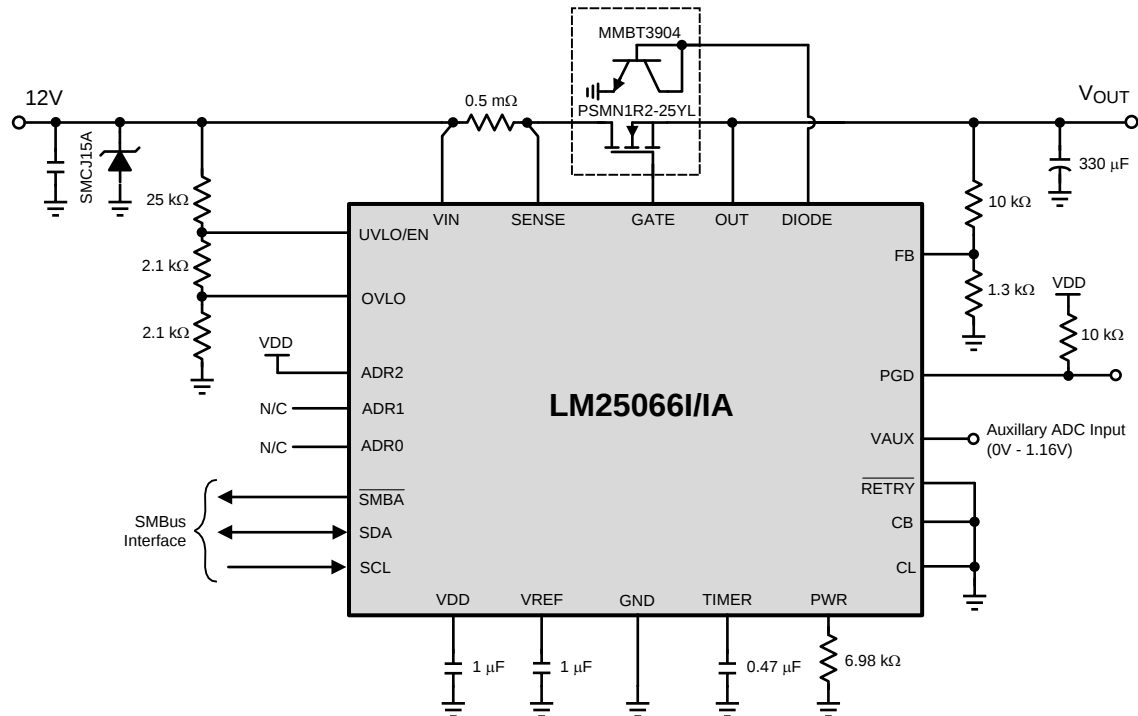


Figure 36. Typical Application Circuit

### DESIGN-IN PROCEDURE

(Refer to Figure 36 for Typical Application Circuit) Shown here is the step-by-step procedure for hardware design of the LM25066I/A. This procedure refers to sections that provide detailed information on the following design steps. The recommended design-in procedure is as follows:

**MOSFET Selection:** Determine MOSFET value based on breakdown voltage, current and power ratings.

**Current Limit,  $R_S$ :** Determine the current limit threshold ( $I_{LIM}$ ). This threshold must be higher than the normal maximum load current, allowing for tolerances in the current sense resistor value and the LM25066I/A Current Limit threshold voltage. Use Equation 1 to determine the value for  $R_S$ .

**Power Limit Threshold:** Determine the maximum allowable power dissipation for the series pass MOSFET ( $Q_1$ ) using the device's SOA information. Use Equation 2 to determine the value for  $R_{PWR}$ .

**Turn-On Time and TIMER Capacitor,  $C_T$ :** Determine the value for the timing capacitor at the TIMER pin ( $C_T$ ) using Equation 8. The fault timeout period ( $t_{FAULT}$ ) **MUST** be longer than the circuit's turn-on-time. The turn-on time can be estimated using the equations in TURN-ON TIME, but should be verified experimentally. Review the resulting insertion time, and the restart timing if retry is enabled.

**UVLO, OVLO:** Choose option A, B, C, or D from UVLO, OVLO to set the UVLO and OVLO thresholds and hysteresis. Use the procedure for the appropriate option to determine the resistor values at the UVLO/EN and OVLO pins.

**Power Good:** Choose the appropriate output voltage and calculate the required resistor divider from the output voltage to the FB pin. Choose either VDD or OUT to connect properly sized pullup resistor for the Power Good output (PGD).

**Refer to Programming Guide section:** After all hardware design is complete, refer to the programming guide for a step by step procedure regarding software.

### MOSFET SELECTION

It is recommended that the external MOSFET ( $Q_1$ ) selection be based on the following criteria:

- The  $BV_{DSS}$  rating should be greater than the maximum system voltage ( $V_{SYS}$ ), plus ringing and transients which can occur at  $V_{SYS}$  when the circuit card, or adjacent cards, are inserted or removed.
- The maximum continuous current rating should be based on the current limit threshold (e.g.  $25\text{ mV}/R_S$ ), not the maximum load current, since the circuit can operate near the current limit threshold continuously.
- The Pulsed Drain Current spec ( $I_{DM}$ ) must be greater than the current threshold for the circuit breaker function ( $45\text{ mV}/R_S$  when  $CL = CB = GND$ ).
- The SOA (Safe Operating Area) chart of the device and its thermal properties should be used to determine the maximum power dissipation threshold set by the  $R_{PWR}$  resistor. The programmed maximum power dissipation should have a reasonable margin from the maximum power defined by the MOSFET's SOA curve (if the device is set to infinitely retry, the MOSFET will be repeatedly stressed during fault restart cycles). The MOSFET manufacturer should be consulted for guidelines.
- $R_{DS(on)}$  should be sufficiently low such that the power dissipation at maximum load current ( $I_{LIM}^2 \times R_{DS(on)}$ ) does not raise its junction temperature above the manufacturer's recommendation.
- The gate-to-source voltage provided by the LM25066I/A can be as high as 18.8V at turn-on when the output voltage is zero. At turn-off, the reverse gate-to-source voltage will be equal to the output voltage at the instant the GATE pin is pulled low. If the device chosen for  $Q_1$  is not rated for these voltages, an external zener diode must be added from its gate to source, with the zener voltage less than the device maximum  $V_{GS}$  rating. The zener diode's working voltage protects the MOSFET during turn-on, and its forward voltage protects the MOSFET during shutoff. The zener diode's forward current rating must be at least 190 mA to conduct the GATE pulldown current when a circuit breaker condition is detected.

## CURRENT LIMIT ( $R_S$ )

The LM25066I/A monitors the current in the external MOSFET  $Q_1$  by measuring the voltage across the sense resistor ( $R_S$ ), connected from VIN to SENSE. The required resistor value is calculated from:

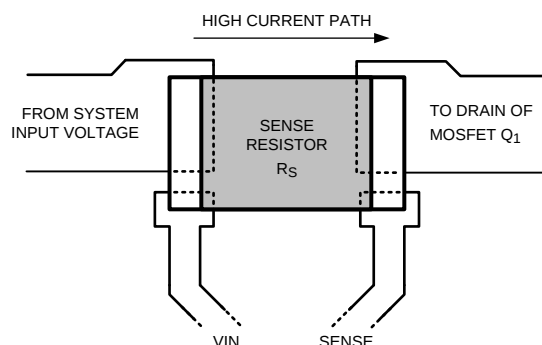
$$R_S = \frac{V_{CL}}{I_{LIM}} \quad (1)$$

where  $I_{LIM}$  is the desired current limit threshold. If the voltage across  $R_S$  reaches  $V_{CL}$ , the current limit circuit modulates the gate of  $Q_1$  to regulate the current at  $I_{LIM}$ . While the current limiting circuit is active, the fault timer is active as described in [Fault Timer and Restart](#). For proper operation,  $R_S$  must be less than 200 m $\Omega$ .

$V_{CL}$  can be set to either 25mV or 46mV via hardware and/or software. This setting defaults to use of CL pin which when grounded is 25mV or high is 46mV. The value when powered can be set via PMBus™ with the MFR\_SPECIFIC\_DEVICE\_SETUP command, which defaults to the 25mV setting.

Once the desired setting is known, calculate the shunt based on that input voltage and maximum current. While the maximum load current in normal operation can be used to determine the required power rating for resistor  $R_S$ , basing it on the current limit value provides a more reliable design since the circuit can operate near the current limit threshold continuously. The resistor's surge capability must also be considered since the circuit breaker threshold is 1.8 or 3.6 times the current limit threshold.

Connections from  $R_S$  to the LM25066I/A should be made using Kelvin techniques. In the suggested layout of [Figure 37](#), the small pads at the lower corners of the sense resistor connect only to the sense resistor terminals and not to the traces carrying the high current. With this technique, only the voltage across the sense resistor is applied to VIN and SENSE, eliminating the voltage drop across the high current solder connections.



**Figure 37. Sense Resistor Connections**

## POWER LIMIT THRESHOLD

The LM25066I/A determines the power dissipation in the external MOSFET ( $Q_1$ ) by monitoring the drain current (the current in  $R_S$ ), and the  $V_{DS}$  of  $Q_1$  (SENSE to OUT pins). The resistor at the PWR pin ( $R_{PWR}$ ) sets the maximum power dissipation for  $Q_1$  and is calculated from [Equation 2](#):

$$R_{PWR} = 1.71 \times 10^5 \times R_S \times P_{MOSFET(LIM)} \quad (2)$$

where  $P_{MOSFET(LIM)}$  is the desired power limit threshold for  $Q_1$  and  $R_S$  is the current sense resistor described in [Current Limit](#). For example, if  $R_S$  is 10 mΩ and the desired power limit threshold is 20W,  $R_{PWR}$  calculates to 34.2 kΩ. If  $Q_1$ 's power dissipation reaches the threshold,  $Q_1$ 's gate is controlled to regulate the load current, keeping  $Q_1$ 's power from exceeding the threshold. For proper operation of the power limiting feature,  $R_{PWR}$  must be ≤150 kΩ. While the power limiting circuit is active, the fault timer is active as described in [Fault Timer and Restart](#). Typically, power limit is reached during startup, or if the output voltage falls because of a severe overload or short circuit. The programmed maximum power dissipation should have a reasonable margin from the maximum power defined by the SOA chart, especially if retry is enabled since the MOSFET will be repeatedly stressed during fault restart cycles. The MOSFET manufacturer should be consulted for guidelines. If the application does not require use of the power limit function, the PWR pin can be left open. The accuracy of the power limit function at turn-on may degrade if a very low value power dissipation limit is set. The reason for this caution is that the voltage across the sense resistor, which is monitored and regulated by the power limit circuit, is lowest at turn-on when the regulated current is at a minimum. The voltage across the sense resistor during power limit can be expressed as follows:

$$V_{SENSE} = I_L \times R_S = \frac{R_{PWR}}{1.71 \times 10^5 \times V_{DS}} = \frac{R_S \times P_{FET(LIM)}}{V_{DS}} \quad (3)$$

where  $I_L$  is the current in  $R_S$  and  $V_{DS}$  is the voltage across  $Q_1$ . For example, if the power limit is set at 20W with  $R_S = 10$  mΩ and  $V_{DS} = 15$ V, the sense resistor voltage calculates to 13.3 mV, which is comfortably regulated by the LM25066I/A. However, if the power limit is set lower (e.g. 2W), the sense resistor voltage calculates to 1.33 mV. At this low level, noise and offsets within the LM25066I/A may degrade the power limit accuracy. To maintain accuracy, the sense resistor voltage should not be less than 5 mV.

## TURN-ON TIME

The output turn-on time depends on whether the LM25066I/A operates in current limit, or in both power limit and current limit, during turn-on.

**A) Turn-on with current limit only:** The current limit threshold ( $I_{LIM}$ ) is determined by the current sense resistor ( $R_S$ ). If the current limit threshold is less than the current defined by the power limit threshold at maximum  $V_{DS}$ , the circuit operates at the current limit threshold only during turn-on. Referring to [Figure 39A](#), as the load current reaches  $I_{LIM}$ , the gate-to-source voltage is controlled at  $V_{GSL}$  to maintain the current at  $I_{LIM}$ . As the output voltage reaches its final value ( $V_{DS} \approx 0$ V) the drain current reduces to its normal operating value. The time for the OUT pin voltage to transition from zero volts to  $V_{SYS}$  is equal to:

$$t_{ON} = \frac{V_{SYS} \times C_L}{I_{LIM}} \quad (4)$$

where  $C_L$  is the load capacitance. For example, if  $V_{SYS} = 12$ V,  $C_L = 1000$  μF, and  $I_{LIM} = 1$ A,  $t_{ON}$  calculates to 12 ms. The maximum instantaneous power dissipated in the MOSFET is 12W. This calculation assumes the time from  $t_1$  to  $t_2$  in [Figure 40\(a\)](#) is small compared to  $t_{ON}$  and the load does not draw any current until after the output voltage has reached its final value, and PGD switches high ([Figure 39A](#)). The Fault Timeout Period must be set longer than  $t_{ON}$  to prevent a fault shutdown before the turn-on sequence is complete.

If the load draws current during the turn-on sequence ([Figure 39B](#)), the turn-on time is longer than the above calculation and is approximately equal to:

$$t_{ON} = -(R_L \times C_L) \times \ln \left[ \frac{(I_{LIM} \times R_L) - V_{SYS}}{(I_{LIM} \times R_L)} \right] \quad (5)$$

where  $R_L$  is the load resistance. The Fault Timeout Period must be set longer than  $t_{ON}$  to prevent a fault shutdown before the turn-on sequence is complete.

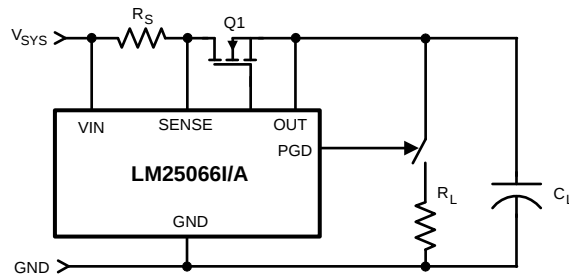
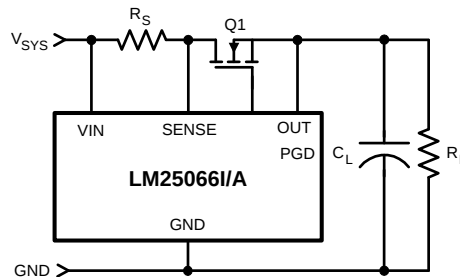


Figure 38. A. No Load Current During Turn-On



Load Draws Current During Turn-On

Figure 39. Current During Turn-On

**B) Turn-On with Power Limit and Current Limit:** The maximum allowed power dissipation in  $Q_1$  ( $P_{MOSFET(LIM)}$ ) is defined by the resistor at the PWR pin, and the current sense resistor  $R_S$ . See [POWER LIMIT THRESHOLD](#). If the current limit threshold ( $I_{LIM}$ ) is higher than the current defined by the power limit threshold at maximum  $V_{DS}$  ( $P_{MOSFET(LIM)}/V_{SYS}$ ), the circuit operates initially in the power limit mode when the  $V_{DS}$  of  $Q_1$  is high and then transitions to current limit mode as the current increases to  $I_{LIM}$  and  $V_{DS}$  decreases. Assuming the load ( $R_L$ ) is not connected during turn-on, the time for the output voltage to reach its final value is approximately equal to:

$$t_{ON} = \frac{C_L \times V_{SYS}^2}{2 \times P_{MOSFET(LIM)}} + \frac{C_L \times P_{MOSFET(LIM)}}{2 \times I_{LIM}^2} \quad (6)$$

For example, if  $V_{SYS} = 12V$ ,  $C_L = 1000 \mu F$ ,  $I_{LIM} = 1A$ , and  $P_{MOSFET(LIM)} = 10W$ ,  $t_{ON}$  calculates to  $\approx 12.2$  ms, and the initial current level ( $I_P$ ) is approximately 0.83A. The Fault Timeout Period must be set longer than  $t_{ON}$ .

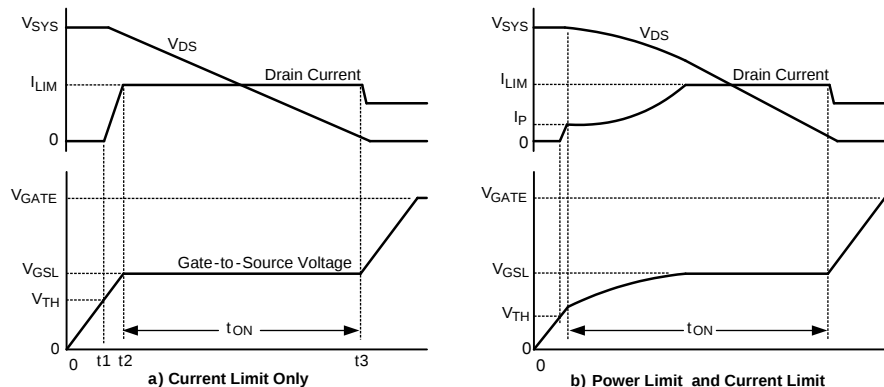


Figure 40. MOSFET Power Up Waveforms

### TIMER CAPACITOR, $C_T$

The TIMER pin capacitor ( $C_T$ ) sets the timing for the insertion time delay, fault timeout period, and the restart timing of the LM25066I/A.

**A) Insertion Delay** - Upon applying the system voltage ( $V_{SYS}$ ) to the circuit, the external MOSFET ( $Q_1$ ) is held off during the insertion time ( $t_1$  in [Figure 32](#)) to allow ringing and transients at  $V_{SYS}$  to settle. Since each backplane's response to a circuit card plug-in is unique, the worst case settling time must be determined for each application. The insertion time starts when VIN reaches the POR threshold, at which time the internal 5.5  $\mu A$  current source charges  $C_T$  from 0V to 1.7V. The required capacitor value is calculated from:

$$C_T = \frac{t_1 \times 5.5 \mu A}{1.7V} = t_1 \times 3.2 \times 10^{-6} \quad (7)$$

For example, if the desired insertion delay is 250 ms,  $C_T$  calculates to 0.8  $\mu F$ . At the end of the insertion delay,  $C_T$  is quickly discharged by a 1.9 mA current sink.

**B) Fault Timeout Period** - During inrush current limiting or upon detection of a fault condition where the current limit and/or power limit circuits regulate the current through  $Q_1$ , the fault timer current source (90  $\mu A$ ) is switched on to charge  $C_T$ . The Fault Timeout Period is the time required for the TIMER pin voltage to reach 1.7V, at which time  $Q_1$  is switched off. The required capacitor value for the desired Fault Timeout Period  $t_{FAULT}$  is calculated from:

$$C_T = \frac{t_{FAULT} \times 90 \mu A}{1.7V} = t_{FAULT} \times 5.3 \times 10^{-5} \quad (8)$$

For example, if the desired Fault Timeout Period is 15 ms,  $C_T$  calculates to 0.8  $\mu F$ .  $C_T$  is discharged by the 2.8  $\mu A$  current sink at the end of the Fault Timeout Period. After the Fault Timeout Period, if retry is disabled, the LM25066I/A latches the GATE pin low until a power up sequence is initiated by external circuitry. When the Fault Timeout Period of the LM25066I/A expires, a restart sequence starts as described below (Restart Timing). During consecutive cycles of the restart sequence, the fault timeout period is shorter than the initial fault timeout period described above by approximately 20% since the voltage at the TIMER pin starts ramping up from 0.3V rather than ground.

Since the LM25066I/A normally operates in power limit and/or current limit during a power up sequence, the Fault Timeout Period **MUST** be longer than the time required for the output voltage to reach its final value. See [TURN-ON TIME](#).

**C) Restart Timing** - For the LM25066I/A, after the Fault Timeout Period described above,  $C_T$  is discharged by the 2.8  $\mu A$  current sink to 1V. The TIMER pin then cycles through seven additional charge/discharge cycles between 1V and 1.7V as shown in [Figure 34](#). The restart time ends when the TIMER pin voltage reaches 0.3V during the final high-to-low ramp. The restart time, after the Fault Timeout Period, is equal to:

$$t_{RESTART} = C_T \times \left[ \frac{7 \times 0.7V}{2.8 \mu A} + \frac{7 \times 0.7V}{90 \mu A} + \frac{1.4V}{2.8 \mu A} \right] \quad (9)$$

$$= C_T \times 2.3 \times 10^6 \quad (10)$$

For example, if  $C_T = 0.8 \mu F$ ,  $t_{RESTART} = 2$  seconds. At the end of the restart time,  $Q_1$  is switched on. If the fault is still present, the fault timeout and restart sequence repeats. The on-time duty cycle of  $Q_1$  is approximately 0.67% in this mode.

## UVLO, OVLO

By programming the UVLO and OVLO thresholds the LM25066I/A enables the series pass device ( $Q_1$ ) when the input supply voltage ( $V_{SYS}$ ) is within the desired operational range. If  $V_{SYS}$  is below the UVLO threshold, or above the OVLO threshold,  $Q_1$  is switched off, denying power to the load. Hysteresis is provided for each threshold.

**Option A:** The configuration shown in [Figure 41](#) requires three resistors (R1-R3) to set the thresholds.

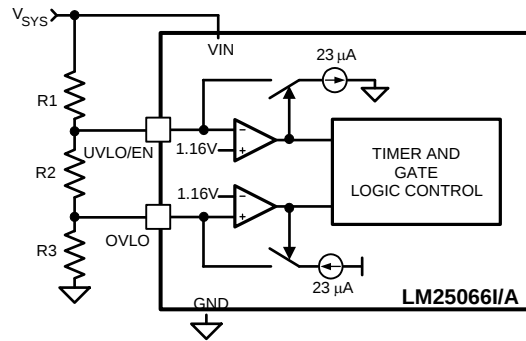


Figure 41. UVLO and OVLO Thresholds Set By R1-R3

The procedure to calculate the resistor values is as follows:

- Choose the upper UVLO threshold ( $V_{UVH}$ ), and the lower UVLO threshold ( $V_{UVL}$ ).
- Choose the upper OVLO threshold ( $V_{OVH}$ ).
- The lower OVLO threshold ( $V_{OVL}$ ) cannot be chosen in advance in this case, but is determined after the values for R1-R3 are determined. If  $V_{OVL}$  must be accurately defined in addition to the other three thresholds, see Option B below. The resistors are calculated as follows:

$$R1 = \frac{V_{UVH} - V_{UVL}}{23 \mu A} = \frac{V_{UV(HYS)}}{23 \mu A} \quad (11)$$

$$R3 = \frac{1.16V \times R1 \times V_{UVL}}{V_{OVH} \times (V_{UVL} - 1.16V)} \quad (12)$$

$$R2 = \frac{1.16V \times R1}{V_{UVL} - 1.16V} - R3 \quad (13)$$

The lower OVLO threshold is calculated from:

$$V_{OVL} = \frac{(R1 + R2) \times ((1.16V) - 23 \mu A) + 1.16V}{R3} \quad (14)$$

As an example, assume the application requires the following thresholds:  $V_{UVH} = 8V$ ,  $V_{UVL} = 7V$ ,  $V_{OVH} = 15V$ .

$$R1 = \frac{8V - 7V}{23 \mu A} = \frac{1V}{23 \mu A} = 43.5 \text{ k}\Omega \quad (15)$$

$$R3 = \frac{1.16V \times R1 \times 7V}{15V \times (7V - 1.16V)} = 4.03 \text{ k}\Omega \quad (16)$$

$$R2 = \frac{1.16V \times R1}{(7V - 1.16V)} - R3 = 4.61 \text{ k}\Omega \quad (17)$$

The lower OVLO threshold calculates to 12.03V and the OVLO hysteresis is 2.97V. Note that the OVLO hysteresis is always slightly greater than the UVLO hysteresis in this configuration. When the R1-R3 resistor values are known, the threshold voltages and hysteresis are calculated from the following:

$$V_{UVH} = 1.16V + [R1 \times (23 \mu A + \frac{1.16V}{(R2 + R3)})] \quad (18)$$

$$V_{UVL} = \frac{1.16V \times (R1 + R2 + R3)}{R2 + R3} \quad (19)$$

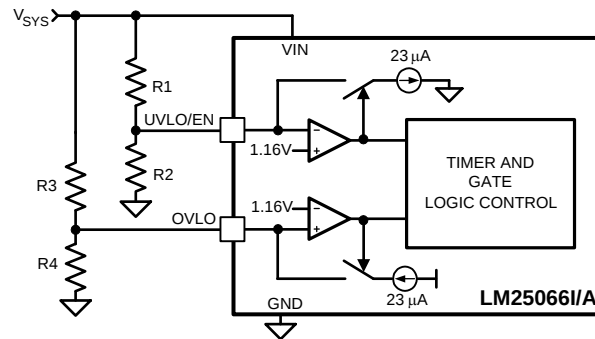
$$V_{UV(HYS)} = R1 \times 23 \mu A \quad (20)$$

$$V_{OVH} = \frac{1.16V \times (R1 + R2 + R3)}{R3} \quad (21)$$

$$V_{OVL} = \frac{(R1 + R2) \times (1.16V) - 23 \mu A}{R3} + 1.16V \quad (22)$$

$$V_{OV(HYS)} = (R1 + R2) \times 23 \mu A \quad (23)$$

**Option B:** If all four thresholds must be accurately defined, the configuration in Figure 42 can be used.



**Figure 42. Programming the Four Thresholds**

The four resistor values are calculated as follows: - Choose the upper and lower UVLO thresholds ( $V_{UVH}$ ) and ( $V_{UVL}$ ).

$$R1 = \frac{V_{UVH} - V_{UVL}}{23 \mu A} = \frac{V_{UV(HYS)}}{23 \mu A} \quad (24)$$

$$R2 = \frac{1.16V \times R1}{(V_{UVL} - 1.16V)} \quad (25)$$

- Choose the upper and lower OVLO threshold ( $V_{OVH}$ ) and ( $V_{OVL}$ ).

$$R3 = \frac{V_{OVH} - V_{OVL}}{23 \mu A} = \frac{V_{OV(HYS)}}{23 \mu A} \quad (26)$$

$$R4 = \frac{1.16V \times R3}{(V_{OVH} - 1.16V)} \quad (27)$$

As an example, assume the application requires the following thresholds:  $V_{UVH} = 8V$ ,  $V_{UVL} = 7V$ ,  $V_{OVH} = 15.5V$ , and  $V_{OVL} = 14V$ . Therefore  $V_{UV(HYS)} = 1V$  and  $V_{OV(HYS)} = 1.5V$ . The resistor values are:

$$R1 = 43.5 \text{ k}\Omega, R2 = 8.64 \text{ k}\Omega$$

$$R3 = 65.2 \text{ k}\Omega, R4 = 5.27 \text{ k}\Omega$$

When the R1-R4 resistor values are known, the threshold voltages and hysteresis are calculated from the following:

$$V_{UVH} = 1.16V + [R1 \times \frac{(1.16V + 23 \mu A)}{R2}] \quad (28)$$

$$V_{UVL} = \frac{1.16V \times (R1 + R2)}{R2} \quad (29)$$

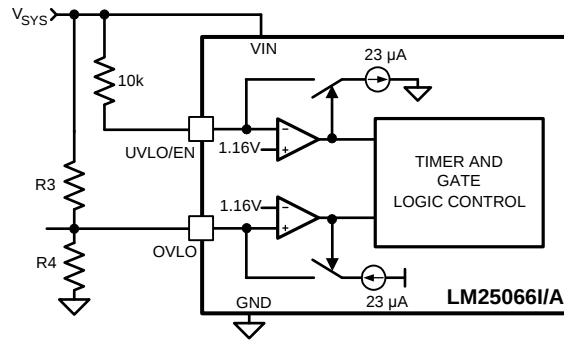
$$V_{UV(HYS)} = R1 \times 23 \mu A \quad (30)$$

$$V_{OVH} = \frac{1.16V \times (R3 + R4)}{R4} \quad (31)$$

$$V_{OVL} = 1.16V + [R3 \times \frac{(1.16V - 23 \mu A)}{R4}] \quad (32)$$

$$V_{OV(HYS)} = R3 \times 23 \mu A \quad (33)$$

**Option C:** The minimum UVLO level is obtained by connecting the UVLO/EN pin to VIN as shown in Figure 43. Q<sub>1</sub> is switched on when the VIN voltage reaches the POR threshold ( $\approx 2.6V$ ). The OVLO thresholds are set using R3, R4. Their values are calculated using the procedure in Option B.

**Figure 43. UVLO = POR**

**Option D:** The OVLO function can be disabled by grounding the OVLO pin. The UVLO thresholds are set as described in Option B or Option C.

### POWER GOOD

When the voltage at the FB pin increases above its threshold, the internal pulldown acting on the PGD pin is disabled allowing PGD to rise to  $V_{PGD}$  through the pullup resistor,  $R_{PG}$ , as shown in Figure 45. The pullup voltage ( $V_{PGD}$ ) can be as high as 17V, and can be higher or lower than the voltages at VIN and OUT. VDD is a convenient choice for  $V_{PGD}$  as it allows interface to low voltage logic and avoids glitching on PGD during power-up. If a delay is required at PGD, suggested circuits are shown in Figure 46. In Figure 46A, capacitor  $C_{PG}$  adds delay to the rising edge, but not to the falling edge. In Figure 46B, the rising edge is delayed by  $R_{PG1} + R_{PG2}$  and  $C_{PG}$ , while the falling edge is delayed a lesser amount by  $R_{PG2}$  and  $C_{PG}$ . Adding a diode across  $R_{PG2}$  (Figure 46C) allows for equal delays at the two edges, or a short delay at the rising edge and a long delay at the falling edge.

Setting the output threshold for the PGD pin requires two resistors ( $R4$ ,  $R5$ ) as shown in Figure 44. While monitoring the output voltage is shown in Figure 44.  $R4$  can be connected to any other voltage which requires monitoring.

The resistor values are calculated as follows:

Choose the upper and lower threshold ( $V_{PGDH}$ ) and ( $V_{PGDL}$ ) at  $V_{OUT}$ .

$$R4 = \frac{V_{PGDH} - V_{PGDL}}{24 \mu A} = \frac{V_{PGD(HYS)}}{24 \mu A}$$

$$R5 = \frac{1.167V \times R4}{(V_{PGDH} - 1.167V)} \quad (34)$$

As an example, assume the application requires the following thresholds:  $V_{PGDH} = 10.14V$ , and  $V_{PGDL} = 9.9V$ . Therefore  $V_{PGD(HYS)} = 0.24V$ . The resistor values are:

$$R4 = 10 \text{ k}\Omega, R5 = 1.3 \text{ k}\Omega$$

Where the  $R4$  and  $R5$  resistor values are known, the threshold voltages and hysteresis are calculated from the following:

$$V_{PGDH} = \frac{1.167V \times (R4 + R5)}{R5}$$

$$V_{PGDL} = 1.167V + [R4 \times \frac{(1.167V + 24 \mu A)}{R5}]$$

$$V_{PGD(HYS)} = R4 \times 24 \mu A$$

(35)

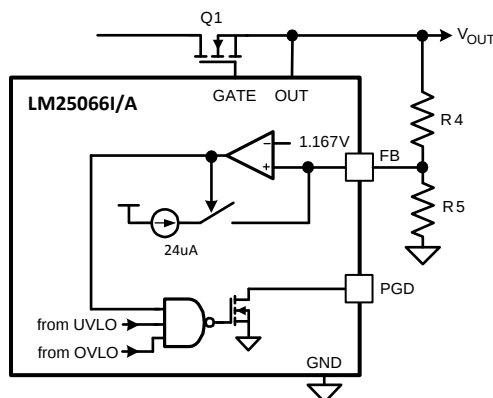


Figure 44. Programming the PGD Threshold

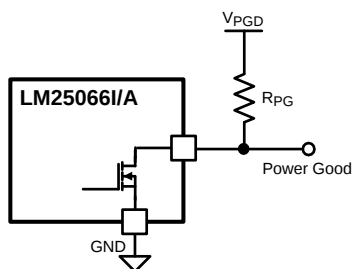


Figure 45. Power Good Output

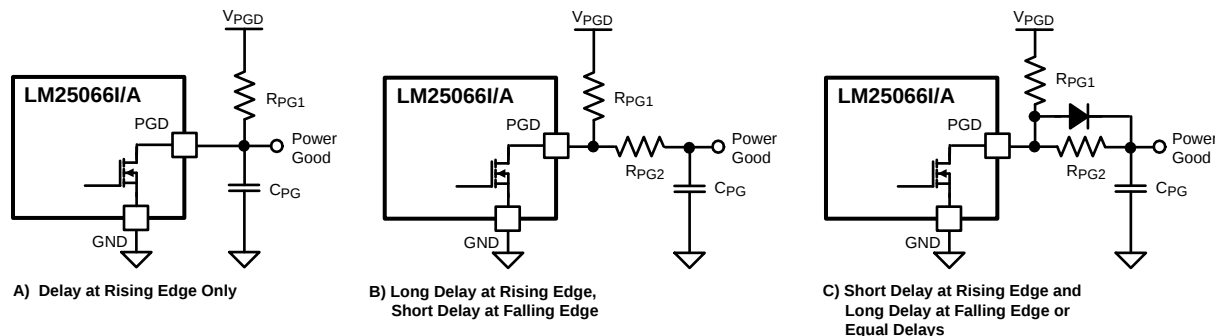
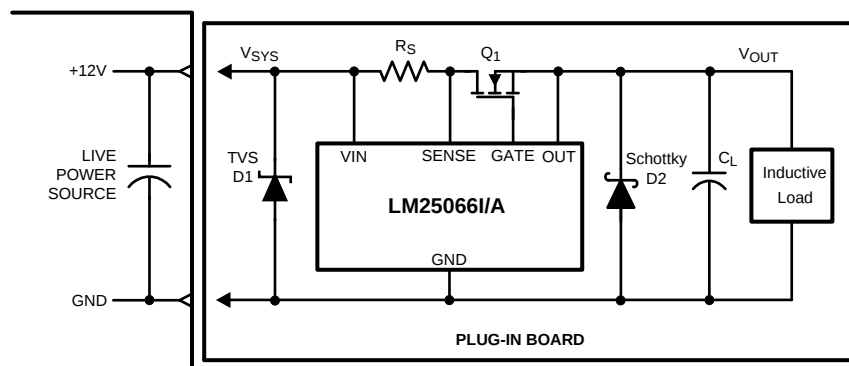


Figure 46. Adding Delay to the Power Good Output Pin

## SYSTEM CONSIDERATIONS

A) Continued proper operation of the LM25066I/A hot-swap circuit normally dictates that capacitance be present on the supply side of the connector into which the hot-swap circuit is plugged in, as depicted in [Figure 47](#). The capacitor in the “LIVE POWER SOURCE” section is necessary to absorb the transient generated whenever the hot-swap circuit shuts off the load current. If the capacitance is not present, parasitic inductance of the supply lines will generate a voltage transient at shut-off which may exceed the absolute maximum rating of the LM25066I/A, resulting in its destruction. A TVS device with appropriate voltage and power ratings can also be connected from VIN to GND to clamp the voltage spike (see application note AN-2100 [SNVA464](#)).

B) If the load powered by the LM25066I/A hot-swap circuit has inductive characteristics, a Schottky diode is required across the LM25066I/A's output along with some load capacitance. The capacitance and diode are necessary to limit the negative excursion at the OUT pin when the load current is shut off. If the OUT pin transitions more than 0.3V negative, the LM25066I/A will internally reset, erasing the volatile setting for retries and warning thresholds. See [Figure 47](#). To alleviate this, a small gate resistance (e.g. 10Ω) can be used. This resistor has the added benefit of damping any high frequency gate voltage oscillations, particularly in paralleled FET arrangements.



**Figure 47. Output Diode Required for Inductive Loads**

## PC BOARD GUIDELINES

The following guidelines should be followed when designing the PC board for the LM25066I/A:

- Place the LM25066I/A close to the board's input connector to minimize trace inductance from the connector to the MOSFET.
- Place a small capacitor,  $C_{IN}$  (1nF), directly adjacent to the VIN and GND pins of the LM25066I/A to help minimize transients which may occur on the input supply line. Transients of several volts can easily occur when the load current is shut off. **ASIDE:** note that if the current drawn by such capacitor is deemed unacceptable, input voltage spike transients can be appropriately minimized by proper placement of a TVS device and operation without this  $C_{IN}$  capacitor becomes feasible.
- Place a 1  $\mu$ F capacitor as close as possible to VREF pin.
- Place a 1  $\mu$ F capacitor as close as possible to VDD pin.
- The sense resistor ( $R_S$ ) should be placed close to the LM25066I/A. In particular, the trace to the VIN pin should be made as low resistance as practical to ensure maximum current and power measurement accuracy. Connect  $R_S$  using the Kelvin techniques shown in [Figure 37](#).
- The high current path from the board's input to the load (via  $Q_1$ ) and the return path should be parallel and close to each other to minimize parasitic loop inductance.
- The ground connections for the various components around the LM25066I/A should be connected directly to each other and to the LM25066I/A's GND pin and then connected to the system ground at one point. Do not connect the various component grounds to each other through the high current ground line. For more details, see application note AN-2100 [SNVA464](#).
- Provide adequate heat sinking for the series pass device ( $Q_1$ ) to help reduce stresses during turn-on and turn-off.
- Keep the gate trace from the LM25066I/A to the pass MOSFET short and direct.
- The board's edge connector can be designed such that the LM25066I/A detects via the UVLO/EN pin that the board is being removed and responds by turning off the load before the supply voltage is disconnected. For example, in [Figure 48](#), the voltage at the UVLO/EN pin goes to ground before  $V_{SYS}$  is removed from the LM25066I/A because of the shorter edge connector pin. When the board is inserted into the edge connector, the system voltage is applied to the LM25066I/A's VIN pin before the UVLO voltage is taken high, thereby allowing the LM25066I/A to turn on the output in a controlled fashion.

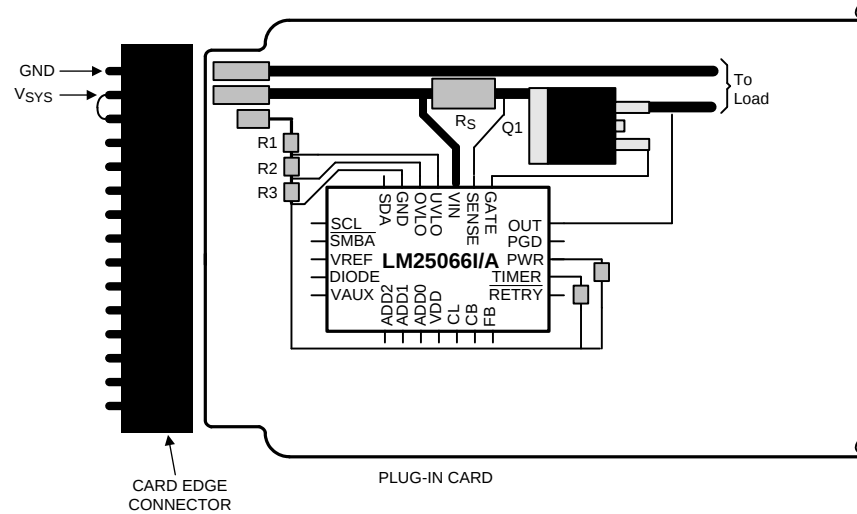


Figure 48. Recommended Board Connector Design

## PMBus™ Command Support

The device features an SMBus interface that allows the use of PMBus™ commands to set warn levels, error masks, and get telemetry on  $V_{IN}$ ,  $V_{OUT}$ ,  $I_{IN}$ ,  $V_{AUX}$ , and  $P_{IN}$ . The supported PMBus™ commands are shown in Table 1.

Table 1. Supported PMBus™ Commands

| Code | Name                | Function                                                                      | R/W       | Number Of Data Bytes | Default Value           |
|------|---------------------|-------------------------------------------------------------------------------|-----------|----------------------|-------------------------|
| 01h  | OPERATION           | Retrieves or stores the operation status.                                     | R/W       | 1                    | 80h                     |
| 03h  | CLEAR_FAULTS        | Clears the status registers and re-arms the black box registers for updating. | Send Byte | 0                    |                         |
| 19h  | CAPABILITY          | Retrieves the device capability.                                              | R         | 1                    | B0h                     |
| 43h  | VOUT_UV_WARN_LIMIT  | Retrieves or stores output under-voltage warn limit threshold.                | R/W       | 2                    | 0000h                   |
| 4Fh  | OT_FAULT_LIMIT      | Retrieves or stores over-temperature fault limit threshold.                   | R/W       | 2                    | 0FFFh (256°C)           |
| 51h  | OT_WARN_LIMIT       | Retrieves or stores over-temperature warn limit threshold.                    | R/W       | 2                    | 0FFFh (256°C)           |
| 57h  | VIN_OV_WARN_LIMIT   | Retrieves or stores input over-voltage warn limit threshold.                  | R/W       | 2                    | 0FFFh                   |
| 58h  | VIN_UV_WARN_LIMIT   | Retrieves or stores input under-voltage warn limit threshold.                 | R/W       | 2                    | 0000h                   |
| 5Dh  | IIN_OC_WARN_LIMIT   | Retrieves or stores input current warn limit threshold (mirror at D3h)        | R/W       | 2                    | 0FFFh                   |
| 78h  | STATUS_BYTE         | Retrieves information about the part operating status.                        | R         | 1                    | 01h                     |
| 79h  | STATUS_WORD         | Retrieves information about the part operating status.                        | R         | 2                    | 0801h                   |
| 7Ah  | STATUS_VOUT         | Retrieves information about output voltage status.                            | R         | 1                    | 00h                     |
| 7Ch  | STATUS_INPUT        | Retrieves information about input status.                                     | R         | 1                    | 10h                     |
| 7Dh  | STATUS_TEMPERATURE  | Retrieves information about temperature status.                               | R         | 1                    | 00h                     |
| 7Eh  | STATUS_CML          | Retrieves information about communications status.                            | R         | 1                    | 00h                     |
| 7Fh  | STATUS_OTHER        | Retrieves other status information                                            | R         | 1                    | 00h                     |
| 80h  | STATUS_MFR_SPECIFIC | Retrieves information about circuit breaker and MOSFET shorted status.        | R         | 1                    | 10h                     |
| 86h  | READ_EIN            | Retrieves energy meter measurement.                                           | R         | 6                    | 00h 00h 00h 00h 00h 00h |

**Table 1. Supported PMBus™ Commands (continued)**

| Code | Name                                     | Function                                                                            | R/W          | Number Of Data Bytes | Default Value                                        |
|------|------------------------------------------|-------------------------------------------------------------------------------------|--------------|----------------------|------------------------------------------------------|
| 88h  | READ_VIN                                 | Retrieves input voltage measurement.                                                | R            | 2                    | 0000h                                                |
| 89h  | READ_IIN                                 | Retrieves input current measurement (Mirror at D1h).                                | R            | 2                    | 0000h                                                |
| 8Bh  | READ_VOUT                                | Retrieves output voltage measurement.                                               | R            | 2                    | 0000h                                                |
| 8Dh  | READ_TEMPERATURE_1                       | Retrieves temperature measurement.                                                  | R            | 2                    | 0000h                                                |
| 97h  | READ_PIN                                 | Retrieves averaged input power measurement (mirror at DFh).                         | R            | 2                    | 0000h                                                |
| 98h  | PMBUS_Revision                           | Retrieves PMBus Revision                                                            | R            | 1                    | 22h                                                  |
| 99h  | MFR_ID                                   | Retrieves manufacturer ID in ASCII characters (TI).                                 | R            | 2                    | 54h<br>49h                                           |
| 9Ah  | MFR_MODEL                                | Retrieves Part number in ASCII characters. (LM25066I).                              | R            | 8                    | 4Ch<br>4Dh<br>32h<br>35h<br>30h<br>36h<br>36h<br>49h |
| 9Bh  | MFR_REVISION                             | Retrieves part revision letter/number in ASCII (e.g. AA).                           | R            | 2                    | 41h A<br>41h A                                       |
| D0h  | MFR_SPECIFIC_00<br>READ_VAUX             | Retrieves auxiliary voltage measurement.                                            | R            | 2                    | 0000h                                                |
| D1h  | MFR_SPECIFIC_01<br>MFR_READ_IIN          | Retrieves input current measurement. (Mirror at 89h)                                | R            | 2                    | 0000h                                                |
| D2h  | MFR_SPECIFIC_02<br>MFR_READ_PIN          | Retrieves input power measurement.                                                  | R            | 2                    | 0000h                                                |
| D3h  | MFR_SPECIFIC_03<br>MFR_IIN_OC_WARN_LIMIT | Retrieves or stores input current limit warn threshold. (Mirror at 5Dh)             | R/W          | 2                    | 0FFFh                                                |
| D4h  | MFR_SPECIFIC_04<br>MFR_PIN_OP_WARN_LIMIT | Retrieves or stores input power limit warn threshold.                               | R/W          | 2                    | 0FFFh                                                |
| D5h  | MFR_SPECIFIC_05<br>READ_PIN_PEAK         | Retrieves measured maximum input power measurement.                                 | R            | 2                    | 0000h                                                |
| D6h  | MFR_SPECIFIC_06<br>CLEAR_PIN_PEAK        | Resets the contents of the peak input power register to zero.                       | Send<br>Byte | 0                    |                                                      |
| D7h  | MFR_SPECIFIC_07<br>GATE_MASK             | Disables external MOSFET gate control for FAULTs.                                   | R/W          | 1                    | 0000h                                                |
| D8h  | MFR_SPECIFIC_08<br>ALERT_MASK            | Retrieves or stores user user fault mask.                                           | R/W          | 2                    | FD04h                                                |
| D9h  | MFR_SPECIFIC_09<br>DEVICE_SETUP          | Retrieves or stores information about number of retry attempts.                     | R/W          | 1                    | 0000h                                                |
| DAh  | MFR_SPECIFIC_10<br>BLOCK_READ            | Retrieves most recent diagnostic and telemetry information in a single transaction. | R            | 12                   | 0460h<br>0000h<br>0000h<br>0000h<br>0000h<br>0000h   |
| DBh  | MFR_SPECIFIC_11<br>SAMPLES_FOR_AVG       | 2^n number of samples to be averaged, range = 00h to 0Ch .                          | R/W          | 1                    | 08h                                                  |
| DCh  | MFR_SPECIFIC_12<br>READ_AVG_VIN          | Retrieves averaged input voltage measurement.                                       | R            | 2                    | 0000h                                                |
| DDh  | MFR_SPECIFIC_13<br>READ_AVG_VOUT         | Retrieves averaged output voltage measurement.                                      | R            | 2                    | 0000h                                                |
| DEh  | MFR_SPECIFIC_14<br>READ_AVG_IIN          | Retrieves averaged input current measurement.                                       | R            | 2                    | 0000h                                                |
| DFh  | MFR_SPECIFIC_15<br>READ_AVG_PIN          | Retrieves averaged input power measurement. (Mirror at 97h)                         | R            | 2                    | 0000h                                                |

**Table 1. Supported PMBus™ Commands (continued)**

| Code | Name                                    | Function                                                                                                                         | R/W | Number Of Data Bytes | Default Value                                      |
|------|-----------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|-----|----------------------|----------------------------------------------------|
| E0h  | MFR_SPECIFIC_16<br>BLACK_BOX_READ       | Captures diagnostic and telemetry information which are latched when the first SMBA alert occurs after faults have been cleared. | R   | 12                   | 0000h<br>0000h<br>0000h<br>0000h<br>0000h<br>0000h |
| E1h  | MFR_SPECIFIC_17<br>READ_DIAGNOSTIC_WORD | Manufacturer-specific parallel of the STATUS_WORD to convey all FAULT/WARN data in a single transaction.                         | R   | 2                    | 0880h                                              |
| E2h  | MFR_SPECIFIC_18<br>AVG_BLOCK_READ       | Retrieves most recent average telemetry and diagnostic information in a single transaction.                                      | R   | 12                   | 0880h<br>0000h<br>0000h<br>0000h<br>0000h<br>0000h |

## Standard PMBus™ Commands

### OPERATION (01h)

The OPERATION command is a standard PMBus™ command that controls the MOSFET switch. This command may be used to switch the MOSFET ON and OFF under host control. It is also used to re-enable the MOSFET after a fault triggered shutdown. Writing an OFF command followed by an ON command will clear all faults. Writing only an ON command after a fault triggered shutdown will not clear the fault registers. The OPERATION command is issued with the write byte protocol.

**Table 2. Recognized OPERATION Command Values**

| Value | Meaning    | Default |
|-------|------------|---------|
| 80h   | Switch ON  | 80h     |
| 00h   | Switch OFF | n/a     |

### CLEAR\_FAULTS (03h)

The CLEAR\_FAULTS command is a standard PMBus™ command that resets all stored warning and fault flags and the SMBA signal. If a fault or warning condition still exists when the CLEAR\_FAULTS command is issued, the SMBA signal may not clear or will re-assert almost immediately. Issuing a CLEAR\_FAULTS command will not cause the MOSFET to switch back on in the event of a fault turn-off: that must be done by issuing an OPERATION command after the fault condition is cleared. This command uses the PMBus™ send byte protocol.

### CAPABILITY (19h)

The CAPABILITY command is a standard PMBus™ command that returns information about the PMBus™ functions supported by the LM25066I/A. This command is read with the PMBus™ read byte protocol.

**Table 3. CAPABILITY Register**

| Value | Meaning                                                         | Default |
|-------|-----------------------------------------------------------------|---------|
| B0h   | Supports Packet Error Check, 400Kbits/sec, Supports SMBus Alert | B0h     |

### VOUT\_UV\_WARN\_LIMIT (43h)

The VOUT\_UV\_WARN\_LIMIT command is a standard PMBus™ command that allows configuring or reading the threshold for the VOUT Under-voltage Warning detection. Reading and writing to this register should use the coefficients shown in Table 44. Accesses to this command should use the PMBus™ read or write word protocol. If the measured value of VOUT falls below the value in this register, VOUT UV Warn Limit flags are set in the respective registers, and the SMBA signal is asserted.

**Table 4. VOUT\_UV\_WARN\_LIMIT Register**

| Value      | Meaning                                        | Default          |
|------------|------------------------------------------------|------------------|
| 1h – 0FFFh | VOUT Under-voltage Warning detection threshold | 0000h (disabled) |
| 0000h      | VOUT Under-voltage Warning disabled            | n/a              |

**OT\_FAULT\_LIMIT (4Fh)**

The OT\_FAULT\_LIMIT is a standard PMBus™ command that allows configuring or reading the threshold for the Overtemperature Fault detection. Reading and writing to this register should use the coefficients shown in Table 44. Accesses to this command should use the PMBus™ read or write word protocol. If the measured temperature exceeds this value, an overtemperature fault is triggered, the MOSFET is switched off, OT Fault flags are set in the respective registers, and the SMBA signal is asserted. After the measured temperature falls below the value in this register, the MOSFET may be switched back on with the OPERATION command. A single temperature measurement is an average of 16 milliseconds of data. Therefore, the temperature fault detection time maybe up to 16 ms.

**Table 5. OT\_FAULT\_LIMIT Register**

| Value      | Meaning                                  | Default       |
|------------|------------------------------------------|---------------|
| 0h – 0FFFh | Overtemperature Fault Threshold Value    | 0FFFh (256°C) |
| 0FFFh      | Overtemperature Fault detection disabled | n/a           |

**OT\_WARN\_LIMIT (51h)**

The OT\_WARN\_LIMIT is a standard PMBus™ command that allows configuring or reading the threshold for the Overtemperature Warning detection. Reading and writing to this register should use the coefficients shown in Table 44. Accesses to this command should use the PMBus™ read or write word protocol. If the measured temperature exceeds this value, an overtemperature warning is triggered, the OT Warn flags are set in the respective registers, and the SMBA signal is asserted. A single temperature measurement is an average of 16 milliseconds of data. Therefore, the temperature warn detection time maybe up to 16 ms.

**Table 6. OT\_WARN\_LIMIT Register**

| Value      | Meaning                                 | Default       |
|------------|-----------------------------------------|---------------|
| 0h – 0FFFh | Overtemperature Warn Threshold Value    | 0FFFh (256°C) |
| 0FFFh      | Overtemperature Warn detection disabled | n/a           |

**VIN\_OV\_WARN\_LIMIT (57h)**

The VIN\_OV\_WARN\_LIMIT is a standard PMBus™ command that allows configuring or reading the threshold for the VIN Over-voltage Warning detection. Reading and writing to this register should use the coefficients shown in Table 44. Accesses to this command should use the PMBus™ read or write word protocol. If the measured value of VIN rises above the value in this register, VIN OV Warn flags are set in the respective registers, and the SMBA signal is asserted.

**Table 7. VIN\_OV\_WARN\_LIMIT Register**

| Value      | Meaning                                      | Default          |
|------------|----------------------------------------------|------------------|
| 0h – 0FFFh | VIN Over-voltage Warning detection threshold | 0FFFh (disabled) |
| 0FFFh      | VIN Over-voltage Warning disabled            | n/a              |

**VIN\_UV\_WARN\_LIMIT (58h)**

The VIN\_UV\_WARN\_LIMIT is a standard PMBus™ command that allows configuring or reading the threshold for the VIN Under-voltage Warning detection. Reading and writing to this register should use the coefficients shown in Table 44. Accesses to this command should use the PMBus™ read or write word protocol. If the measured value of VIN falls below the value in this register, VIN UV Warn flags are set in the respective registers, and the SMBA signal is asserted.

**Table 8. VIN\_UV\_WARN\_LIMIT Register**

| Value      | Meaning                                       | Default          |
|------------|-----------------------------------------------|------------------|
| 1h – 0FFFh | VIN Under-voltage Warning detection threshold | 0000h (disabled) |
| 0000h      | VIN Under-voltage Warning disabled            | n/a              |

**IIN\_OC\_WARN\_LIMIT (5Dh)**

The IIN\_OC\_WARN\_LIMIT command is a standard PMBus command that allows configuring or reading the threshold for the input current, over current warning. For access to this command use the PMBus Read or Write word protocol. The coefficients show in table 43. To read data use the SMBus Read Word protocol. To write data use the SMBus Write Word protocol. Sets the input current threshold above which a warning will be generated. (Mirror at D3h)

**STATUS\_BYTE (78h)**

The STATUS\_BYTE command is a standard PMBus™ command that returns the value of a number of flags indicating the state of the LM25066I/A. Accesses to this command should use the PMBus™ read byte protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command issued.

**Table 9. STATUS\_BYTE Definitions**

| Bit | NAME              | Meaning                                                               | Default |
|-----|-------------------|-----------------------------------------------------------------------|---------|
| 7   | BUSY              | Not Supported, always 0                                               | 0       |
| 6   | OFF               | This bit is asserted if the MOSFET is not switched on for any reason. | 0       |
| 5   | VOUT OV           | Not Supported, always 0                                               | 0       |
| 4   | IOUT OC           | OC Fault or OP Fault                                                  | 0       |
| 3   | VIN UV FAULT      | A VIN Under-voltage Fault has occurred                                | 0       |
| 2   | TEMPERATURE       | A Temperature Fault or Warning has occurred                           | 0       |
| 1   | CML               | A Communication Fault has occurred                                    | 0       |
| 0   | None of the Above | A fault or warning not listed in bits [7:1] has occurred              | 1       |

**STATUS\_WORD (79h)**

The STATUS\_WORD command is a standard PMBus™ command that returns the value of a number of flags indicating the state of the LM25066I/A. Accesses to this command should use the PMBus™ read word protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command issued. The INPUT and VIN UV FAULT flags will default to 1 on startup. However, they will be cleared to 0 after the first time the input voltage exceeds the resistor programmed UVLO threshold.

**Table 10. STATUS\_WORD Definitions**

| Bit | NAME         | Meaning                                                               | Default |
|-----|--------------|-----------------------------------------------------------------------|---------|
| 15  | VOUT         | An output voltage fault or warning has occurred                       | 0       |
| 14  | IOUT/POUT    | Not Supported, always 0                                               | 0       |
| 13  | INPUT        | An input voltage or current fault has occurred                        | 0       |
| 12  | FET Fail     | FET Fail                                                              | 0       |
| 11  | POWER GOOD   | The Power Good signal has been negated                                | 1       |
| 10  | FANS         | Not Supported, always 0                                               | 0       |
| 9   | CB Fault     | Circuit Breaker Fault has occurred                                    | 0       |
| 8   | UNKNOWN      | Not Supported, always 0                                               | 0       |
| 7   | BUSY         | Not Supported, always 0                                               | 0       |
| 6   | OFF          | This bit is asserted if the MOSFET is not switched on for any reason. | 0       |
| 5   | VOUT OV      | Not Supported, always 0                                               | 0       |
| 4   | IOUT OC/OP   | IIN overcurrent fault or FET dissipation fault                        | 0       |
| 3   | VIN UV FAULT | A VIN Under-voltage Fault has occurred                                | 0       |
| 2   | TEMPERATURE  | A Temperature Fault or Warning has occurred                           | 0       |

**Table 10. STATUS\_WORD Definitions (continued)**

| Bit | NAME              | Meaning                                                  | Default |
|-----|-------------------|----------------------------------------------------------|---------|
| 1   | CML               | A Communication Fault has occurred                       | 0       |
| 0   | None of the Above | A fault or warning not listed in bits [7:1] has occurred | 1       |

**STATUS\_VOUT (7Ah)**

The STATUS\_VOUT command is a standard PMBus™ command that returns the value of the VOUT UV Warning flag. Accesses to this command should use the PMBus™ read byte protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command issued.

**Table 11. STATUS\_VOUT Definitions**

| Bit | NAME                | Meaning                                   | Default |
|-----|---------------------|-------------------------------------------|---------|
| 7   | VOUT OV Fault       | Not Supported, always 0                   | 0       |
| 6   | VOUT OV Warn        | Not Supported, always 0                   | 0       |
| 5   | VOUT UV Warn        | A VOUT Under-voltage Warning has occurred | 0       |
| 4   | VOUT UV Fault       | Not Supported, always 0                   | 0       |
| 3   | VOUT Max            | Not Supported, always 0                   | 0       |
| 2   | TON Max Fault       | Not Supported, always 0                   | 0       |
| 1   | TOFF Max Fault      | Not Supported, always 0                   | 0       |
| 0   | VOUT Tracking Error | Not Supported, always 0                   | 0       |

**STATUS\_INPUT (7Ch)**

The STATUS\_INPUT command is a standard PMBus™ command that returns the value of a number of flags related to input voltage, current, and power. Accesses to this command should use the PMBus™ read byte protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command issued. The VIN UV Warn flag will default to 1 on startup. However, it will be cleared to 0 after the first time the input voltage exceeds the resistor programmed UVLO threshold.

**Table 12. STATUS\_INPUT Definitions**

| Bit | NAME                 | Meaning                                  | Default |
|-----|----------------------|------------------------------------------|---------|
| 7   | VIN OV Fault         | A VIN Over-voltage Fault has occurred    | 0       |
| 6   | VIN OV Warn          | A VIN Over-voltage Warning has occurred  | 0       |
| 5   | VIN UV Warn          | A VIN Under-voltage Warning has occurred | 1       |
| 4   | VIN UV Fault         | A VIN Under-voltage Fault has occurred   | 0       |
| 3   | Insufficient Voltage | Not Supported, always 0                  | 0       |
| 2   | IIN OC Fault         | An IIN Over-current Fault has occurred   | 0       |
| 1   | IIN OC Warn          | An IIN Over-current Warning has occurred | 0       |
| 0   | PIN OP Warn          | A PIN Over-power Warning has occurred    | 0       |

**STATUS\_TEMPERATURE (7Dh)**

The STATUS\_TEMPERATURE is a standard PMBus™ command that returns the value of the of a number of flags related to the temperature telemetry value. Accesses to this command should use the PMBus™ read byte protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command issued.

**Table 13. STATUS\_TEMPERATURE Definitions**

| Bit | NAME            | Meaning                                 | Default |
|-----|-----------------|-----------------------------------------|---------|
| 7   | Overtemp Fault  | An Overtemperature Fault has occurred   | 0       |
| 6   | Overtemp Warn   | An Overtemperature Warning has occurred | 0       |
| 5   | Undertemp Warn  | Not Supported, always 0                 | 0       |
| 4   | Undertemp Fault | Not Supported, always 0                 | 0       |
| 3   | reserved        | Not Supported, always 0                 | 0       |

**Table 13. STATUS\_TEMPERATURE Definitions (continued)**

| Bit | NAME     | Meaning                 | Default |
|-----|----------|-------------------------|---------|
| 2   | reserved | Not Supported, always 0 | 0       |
| 1   | reserved | Not Supported, always 0 | 0       |
| 0   | reserved | Not Supported, always 0 | 0       |

**STATUS\_CML (7Eh)**

The STATUS\_CML command is a standard PMBus™ command that returns the value of a number of flags related to communication faults. Accesses to this command should use the PMBus™ read byte protocol. To clear bits in this register, a CLEAR\_FAULTS command should be issued.

**Table 14. STATUS\_CML Definitions**

| Bit | NAME                                                         | Default |
|-----|--------------------------------------------------------------|---------|
| 7   | Invalid or unsupported command received                      | 0       |
| 6   | Invalid or unsupported data received                         | 0       |
| 5   | Packet Error Check failed                                    | 0       |
| 4   | Memory Fault Detected Not supported, always 0                | 0       |
| 3   | Processor Fault Detected Not supported, always 0             | 0       |
| 2   | Reserved, always 0                                           | 0       |
| 1   | Miscellaneous communications fault has occurred              | 0       |
| 0   | Other memory or logic fault detected Not supported, always 0 | 0       |

**STATUS\_OTHER (7Fh)**

| Bit | NAME                    | Default |
|-----|-------------------------|---------|
| 7   | Reserved: always 0      | 0       |
| 6   | Reserved: always 0      | 0       |
| 5   | CB Fault                | 0       |
| 4   | Not supported: Always 0 | 0       |
| 3   | Not supported: Always 0 | 0       |
| 2   | Not supported: Always 0 | 0       |
| 1   | Not supported: Always 0 | 0       |
| 0   | Not supported: Always 0 | 0       |

**STATUS\_MFR\_SPECIFIC (80h)**

The STATUS\_MFR\_SPECIFIC command is a standard PMBus™ command that contains manufacturer specific status information. Accesses to this command should use the PMBus™ read byte protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command should be issued. The default loaded status does not create an SMB Alert State.

**Table 15. STATUS\_MFR\_SPECIFIC Definitions**

| Bit | Meaning                        | Default |
|-----|--------------------------------|---------|
| 7   | Circuit breaker fault          | 0       |
| 6   | Ext. MOSFET shorted fault      | 0       |
| 5   | Not Supported, Always 0        | 0       |
| 4   | Defaults loaded <sup>(1)</sup> | 1       |
| 3   | Not supported: Always 0        | 0       |
| 2   | Not supported: Always 0        | 0       |
| 1   | Not supported: Always 0        | 0       |
| 0   | Not supported: Always 0        | 0       |

(1) Bit 4, Defaults loaded, does not set an SMBAlert.

**READ\_EIN (86h)**

The READ\_EIN command is a standard PMBus command that returns information the host can use to calculate average input power consumption. Accesses to this command should use the PMBus Block Read protocol. Information provided by this command is independent of any device specific averaging period. Six bytes of data are returned by this command. The first two bytes are the two's complement, signed output of an accumulator that continuously sums samples of the instantaneous input power. These two data bytes are formatted in the DIRECT format. The third data byte is a count of the rollover events for the accumulator. This byte is an unsigned integer indicating the number of times that the accumulator has rolled over from its maximum positive value (7FFFh) to zero. The last three data bytes are a 24 bit unsigned integer that counts the number of samples of the instantaneous input power that have been applied to the accumulator.

The combination of the accumulator and the rollover count may overflow within a few seconds. It is left to the host software to detect this overflow and handle it appropriately. Similarly, the sample count value will overflow, but this event only occurs once every few hours.

To convert the data obtained with the READ\_EIN command to average power, first convert the accumulator and rollover count to an unsigned integer:

Accumulator\_23 = (rollover\_count << 15) + accumulator

overflow detection and handling should be done on the 23 bits of accumulator data and the sample count now. Data from the previous calculation should be saved and will be used in this calculation to get the unscaled average power:

$$\frac{\text{Accumulator\_23 [n]} - \text{Accumulator\_23 [n-1]}}{\text{Sample\_count [n]} - \text{Sample\_count [n-1]}} \quad (36)$$

Where:

accumulator\_23 [n] = overflow corrected, 23 bit accumulator data from this read

Sample\_count [n] = Sample count data from this read

accumulator\_23[n-1]= overflow corrected, 23 bit accumulator data from previous read

Sample\_count [n-1] = Sample Count data from previous read

unscaled Average Power is now in the same units as the data from the READ\_PIN command. Coefficients from Table 43 are used to convert the Unscaled Average Power to Watts.

**Table 16. READ\_EIN**

| Bit | Meaning                          | Default |
|-----|----------------------------------|---------|
| 0   | Sample Count High byte           | 0       |
| 1   | Sample Count Mid byte            | 0       |
| 2   | Sample Count Low byte            | 0       |
| 3   | Power Accumulator Rollover Count | 0       |
| 4   | Power Accumulator High Byte      | 0       |
| 5   | Power Accumulator Low Byte       | 0       |
| 6   | Number of Bytes                  | 6       |

**READ\_VIN (88h)**

The READ\_VIN command is a standard PMBus™ command that returns the 12-bit measured value of the input voltage. Reading this register should use the coefficients shown in Table 44. Accesses to this command should use the PMBus™ read word protocol. This value is also used internally for the VIN Over and Under Voltage Warning detection.

**Table 17. READ\_VIN Register**

| Value      | Meaning                | Default |
|------------|------------------------|---------|
| 0h – 0FFFh | Measured value for VIN | 0000h   |

### READ\_VOUT (8Bh)

The READ\_VOUT command is a standard PMBus™ command that returns the 12-bit measured value of the output voltage. Reading this register should use the coefficients shown in [Table 44](#). Accesses to this command should use the PMBus™ read word protocol. This value is also used internally for the VOUT Under Voltage Warning detection.

**Table 18. READ\_VOUT Register**

| Value      | Meaning                 | Default |
|------------|-------------------------|---------|
| 0h – 0FFFh | Measured value for VOUT | 0000h   |

### READ\_IIN (89h)

The READ\_IIN command is a standard PMBus™ command that returns the 12-bit measured value of the input current. Returns instantaneous current. Reading this register should use the coefficients shown in [Table 44](#). Accesses to this command should use the PMBus™ read word protocol. This value is also mirrored at (D1H)

**Table 19. READ\_IIN Register**

| Value      | Meaning                | Default |
|------------|------------------------|---------|
| 0h – 0FFFh | Measured value for IIN | 0000h   |

### READ\_PIN (97h)

The READ\_IIN command is a standard PMBus™ command that returns the 12-bit measured value of the input current. Returns average power Reading this register should use the coefficients shown in [Table 44](#). Accesses to this command should use the PMBus™ read word protocol. This value is also mirrored at (DFh)

**Table 20. READ\_PIN Register**

| Value      | Meaning                | Default |
|------------|------------------------|---------|
| 0h – 0FFFh | Measured value for PIN | 0000h   |

### READ\_TEMPERATURE\_1 (8Dh)

The READ\_TEMPERATURE\_1 command is a standard PMBus™ command that returns the signed value of the temperature measured by the external temperature sense diode. Reading this register should use the coefficients shown in [Table 44](#). Accesses to this command should use the PMBus™ read word protocol. This value is also used internally for the Over Temperature Fault and Warning detection. This data has a range of -256°C to +255°C after the coefficients are applied.

**Table 21. READ\_TEMPERATURE\_1 Register**

| Value      | Meaning                        | Default |
|------------|--------------------------------|---------|
| 0h – 0FFFh | Measured value for TEMPERATURE | 0000h   |

### MFR\_ID (99h)

The MFR\_ID command is a standard PMBus™ command that returns the identification of the manufacturer. To read the MFR\_ID, use the PMBus™ block read protocol.

**Table 22. MFR\_ID Register**

| Byte | Name            | Value   |
|------|-----------------|---------|
| 0    | Number of bytes | 02h     |
| 1    | MFR ID-1        | 54h 'T' |
| 2    | MFR ID-2        | 49h 'I' |

**MFR\_MODEL (9Ah)**

The MFR\_MODEL command is a standard PMBus™ command that returns the part number of the chip. To read the MFR\_MODEL, use the PMBus™ block read protocol.

**Table 23. MFR\_MODEL Register**

| Byte | Name            | Value   |
|------|-----------------|---------|
| 0    | Number of bytes | 08h     |
| 1    | MFR ID-1        | 4Ch 'L' |
| 2    | MFR ID-2        | 4Dh 'M' |
| 3    | MFR ID-3        | 32h '2' |
| 4    | MFR ID-4        | 35h '5' |
| 5    | MFR ID-5        | 30h '0' |
| 6    | MFR ID-6        | 36h '6' |
| 7    | MFR ID-7        | 36h '6' |
| 8    | MFR ID-8        | 49h 'I' |

**MFR\_REVISION (9Bh)**

The MFR\_REVISION command is a standard PMBus™ command that returns the revision level of the part. To read the MFR\_REVISION, use the PMBus™ block read protocol.

**Table 24. MFR\_REVISION Register**

| Byte | Name            | Value   |
|------|-----------------|---------|
| 0    | Number of bytes | 02h     |
| 1    | MFR ID-1        | 41h 'A' |
| 2    | MFR ID-2        | 41h 'A' |

**Manufacturer Specific PMBus™ Commands****MFR\_SPECIFIC\_00: READ\_VAUX (D0h)**

The READ\_VAUX command will report the 12-bit ADC measured auxiliary voltage. Voltages greater than or equal to 1.16V to ground will be reported at plus full scale (0FFFh). Voltages less than or equal to 0V referenced to ground will be reported as 0 (0000h). Coefficients for the VAUX value are dependent on the value of the external divider (if used). To read data from the READ\_VAUX command, use the PMBus™ Read Word protocol.

**Table 25. READ\_VAUX Register**

| Value      | Meaning                       | Default |
|------------|-------------------------------|---------|
| 0h – 0FFFh | Measured value for VAUX input | 0000h   |

**MFR\_SPECIFIC\_01: MFR\_READ\_IIN (D1h)**

The MFR\_READ\_IIN command will report the 12-bit ADC measured current sense voltage. To read data from the MFR\_READ\_IIN command, use the PMBus™ Read Word protocol. Reading this register should use the coefficients shown in [Table 44](#). Please see the section on coefficient calculations to calculate the values to use.

**Table 26. MFR\_READ\_IIN Register**

| Value      | Meaning                                        | Default |
|------------|------------------------------------------------|---------|
| 0h – 0FFFh | Measured value for input current sense voltage | 0000h   |

### MFR\_SPECIFIC\_02: MFR\_READ\_PIN (D2h)

The MFR\_READ\_PIN command will report the upper 12 bits of the VIN x IIN product as measured by the 12-bit ADC. To read data from the MFR\_READ\_PIN command, use the PMBus™ Read Word protocol. Reading this register should use the coefficients shown in [Table 44](#). Please see the section on coefficient calculations to calculate the values to use.

**Table 27. MFR\_READ\_PIN Register**

| Value      | Meaning                                 | Default |
|------------|-----------------------------------------|---------|
| 0h – 0FFFh | Value for input current x input voltage | 0000h   |

### MFR\_SPECIFIC\_03: MFR\_IIN\_OC\_WARN\_LIMIT (D3h)

The MFR\_IIN\_OC\_WARN\_LIMIT PMBus™ command sets the input over-current warning threshold. In the event that the input current rises above the value set in this register, the IIN over-current flags are set in the status registers and the SMBA is asserted. To access the MFR\_IIN\_OC\_WARN\_LIMIT register, use the PMBus™ Read/Write Word protocol. Reading/writing to this register should use the coefficients shown in [Table 44](#).

**Table 28. MFR\_IIN\_OC\_WARN\_LIMIT Register**

| Value      | Meaning                                 | Default |
|------------|-----------------------------------------|---------|
| 0h – 0FFFh | Value for input over-current warn limit | 0FFFh   |
| 0FFFh      | Input over-current warning disabled     | n/a     |

### MFR\_SPECIFIC\_04: MFR\_PIN\_OP\_WARN\_LIMIT (D4h)

The MFR\_PIN\_OP\_WARN\_LIMIT PMBus™ command sets the input over-power warning threshold. In the event that the input power rises above the value set in this register, the PIN Over-power flags are set in the status registers and the SMBA is asserted. To access the MFR\_PIN\_OP\_WARN\_LIMIT register, use the PMBus™ Read/Write Word protocol. Reading/writing to this register should use the coefficients shown in [Table 44](#).

**Table 29. MFR\_PIN\_OP\_WARN\_LIMIT Register**

| Value      | Meaning                               | Default |
|------------|---------------------------------------|---------|
| 0h – 0FFFh | Value for input over-power warn limit | 0FFFh   |
| 0FFFh      | Input over-power warning disabled     | n/a     |

### MFR\_SPECIFIC\_05: READ\_PIN\_PEAK (D5h)

The READ\_PIN\_PEAK command will report the maximum input power measured since a Power-On-Reset or the last CLEAR\_PIN\_PEAK command. To access the READ\_PIN\_PEAK command, use the PMBus™ Read Word protocol. Use the coefficients shown in [Table 44](#).

**Table 30. READ\_PIN\_PEAK Register**

| Value      | Meaning                                                                   | Default |
|------------|---------------------------------------------------------------------------|---------|
| 0h – 0FFFh | Maximum value for input current x input voltage since reset or last clear | 0h      |

### MFR\_SPECIFIC\_06: CLEAR\_PIN\_PEAK (D6h)

The CLEAR\_PIN\_PEAK command will clear the PIN\_PEAK register. This command uses the PMBus™ Send Byte protocol.

### MFR\_SPECIFIC\_07: GATE\_MASK (D7h)

The GATE\_MASK register allows the hardware to prevent fault conditions from switching off the MOSFET. When the bit is high, the corresponding FAULT has no control over the MOSFET gate. All status registers will still be updated (STATUS, DIAGNOSTIC) and an SMBA will still be issued. This register is accessed with the PMBus™ Read / Write Byte protocol.

**WARNING**

**Inhibiting the MOSFET switch off in response to over-current or circuit breaker fault conditions will likely result in the destruction of the MOSFET! This functionality should be used with great care and supervision!**

**Table 31. GATE\_MASK Register**

| Bit | NAME                  | Default |
|-----|-----------------------|---------|
| 7   | Not used, always 0    | 0       |
| 6   | Not used, always 0    | 0       |
| 5   | VIN UV FAULT          | 0       |
| 4   | VIN OV FAULT          | 0       |
| 3   | IIN/PFET FAULT        | 0       |
| 2   | OVERTEMP FAULT        | 0       |
| 1   | Not used, always 0    | 0       |
| 0   | CIRCUIT BREAKER FAULT | 0       |

The IIN/PFET Fault refers to the input current fault and the MOSFET power dissipation fault. There is no input power fault detection, only input power warning detection.

**MFR\_SPECIFIC\_08: ALERT\_MASK (D8h)**

The ALERT\_MASK is used to mask the  $\overline{\text{SMBA}}$  when a specific fault or warning has occurred. Each bit corresponds to one of the 14 different analog and digital faults or warnings that would normally result in an  $\overline{\text{SMBA}}$  being set. When the corresponding bit is high, that condition will not cause the  $\overline{\text{SMBA}}$  to be asserted. If that condition occurs, the registers where that condition is captured will still be updated (STATUS registers, DIAGNOSTIC\_WORD) and the external MOSFET gate control will still be active (VIN\_OV\_FAULT, VIN\_UV\_FAULT, IIN/PFET\_FAULT, CB\_FAULT, OT\_FAULT). This register is accessed with the PMBus™ Read / Write Word protocol. The VIN UNDERVOLTAGE FAULT flag will default to 1 on startup. However, it will be cleared to 0 after the first time the input voltage exceeds the resistor programmed UVLO threshold.

**Table 32. ALERT\_MASK Definitions**

| BIT | NAME                                  | DEFAULT |
|-----|---------------------------------------|---------|
| 15  | VOUT UNDERVOLTAGE WARN                | 1       |
| 14  | IIN LIMIT Warn                        | 1       |
| 13  | VIN UNDERVOLTAGE WARN                 | 1       |
| 12  | VIN OVERVOLTAGE WARN                  | 1       |
| 11  | POWER GOOD                            | 1       |
| 10  | OVERTEMP WARN                         | 1       |
| 9   | Not Used, always 0                    | 0       |
| 8   | OVERPOWER LIMIT WARN                  | 1       |
| 7   | Not Used, always 0                    | 0       |
| 6   | EXT_MOSFET_SHORTED                    | 0       |
| 5   | VIN UNDERVOLTAGE FAULT <sup>(1)</sup> | 0       |
| 4   | VIN OVERVOLTAGE FAULT                 | 0       |
| 3   | IIN/PFET FAULT                        | 0       |
| 2   | OVERTEMPERATURE FAULT                 | 1       |
| 1   | CML FAULT (Communications Fault)      | 0       |
| 0   | CIRCUIT BREAKER FAULT                 | 0       |

(1) VIN\_UV\_FAULT initializes after power up as masked. When VIN exceeds the hardware threshold the mask bit is automatically cleared.

**MFR\_SPECIFIC\_09: DEVICE\_SETUP (D9h)**

The DEVICE\_SETUP command may be used to override pin settings to define operation of the LM25066I/A under host control. This command is accessed with the PMBus™ read / write byte protocol.

**Table 33. DEVICE\_SETUP Byte Format**

| Bit | Name                          | Meaning                      |
|-----|-------------------------------|------------------------------|
| 7:5 | Retry setting                 | 111 = Unlimited retries      |
|     |                               | 110 = Retry 16 times         |
|     |                               | 101 = Retry 8 times          |
|     |                               | 100 = Retry 4 times          |
|     |                               | 011 = Retry 2 times          |
|     |                               | 010 = Retry 1 time           |
|     |                               | 001 = No retries             |
|     |                               | 000 = Pin configured retries |
| 4   | Current limit setting         | 0 = Low setting (25mV)       |
|     |                               | 1 = High setting (46mV)      |
| 3   | CB/CL Ratio                   | 0 = Low setting (1.8x)       |
|     |                               | 1 = High setting (3.6x)      |
| 2   | Current limit Configuration   | 0 = Use pin settings         |
|     |                               | 1 = Use SMBus settings       |
| 1   | Circuit Breaker Configuration | 0 = Use pin settings         |
|     |                               | 1 = Use SMBus settings       |
| 0   | Unused                        |                              |

In order to configure the Current Limit Setting via this register, it is necessary to set the Current Limit Configuration bit (2) to 1 to enable the register to control the current limit function and the Current Limit Setting bit (4) to select the desired setting. Similarly, in order to control the Circuit Breaker via this register, it is necessary to set the Circuit Breaker Configuration bit (1) to 1 to enable the register to control the Circuit Breaker Setting, and the Circuit Breaker / Current Limit Ratio bit (3) to the desired value. If the respective Configuration bits are not set, the Settings will be ignored and the pin set values used.

The Current Limit Configuration effects the coefficients used for the Current and Power measurements and warning registers.

**MFR\_SPECIFIC\_10: BLOCK\_READ (DAh)**

The BLOCK\_READ command concatenates the DIAGNOSTIC\_WORD with input and output telemetry information (IIN, VOUT, VIN, PIN) as well as TEMPERATURE to capture all of the operating information of the LM25066I/A in a single SMBus transaction. The block is 12 bytes long with telemetry information being sent out in the same manner as if an individual READ\_XXX command had been issued (shown below). The contents of the block read register are updated every clock cycle (85ns) as long as the SMBus interface is idle. BLOCK\_READ also specifies that the VIN, VOUT, IIN and PIN measurements are all time-aligned whereas there is a chance they may not be if read with individual PMBus™ commands.

The BLOCK\_READ command is read via the PMBus™ block read protocol.

**Table 34. BLOCK\_READ Register Format**

|                        |          |
|------------------------|----------|
| Byte Count (always 12) | (1 byte) |
| DIAGNOSTIC_WORD        | (1 Word) |
| IIN_BLOCK              | (1 Word) |
| VOUT_BLOCK             | (1 Word) |
| VIN_BLOCK              | (1 Word) |
| PIN_BLOCK              | (1 Word) |
| TEMP_BLOCK             | (1 Word) |

**MFR\_SPECIFIC\_11: SAMPLES\_FOR\_AVG (DBh)**

The SAMPLES\_FOR\_AVERAGE is a manufacturer specific command for setting the number of samples used in computing the average values for IIN, VIN, VOUT, PIN. The decimal equivalent of the AVGN nibble is the power of 2 samples (e.g. AVGN=12 equates to 4096 samples used in computing the average). The LM25066I/A supports average numbers of 1, 2, 4, 8, 16, 32, 64, 128, 256, 512, 1024, 2048, 4096. The SAMPLES\_FOR\_AVG number applies to average values of IIN, VIN, VOUT, PIN simultaneously. The LM25066I/A uses simple averaging. This is accomplished by summing consecutive results up to the number programmed, then dividing by the number of samples. Averaging is calculated according to the following sequence:

$$Y = (X_{(N)} + X_{(N-1)} + \dots + X_{(0)}) / 2^{AVGN} \quad (37)$$

When the averaging has reached the end of a sequence (for example, 4096 samples are averaged), then a whole new sequence begins that will require the same number of samples (in this example, 4096) to be taken before the new average is ready.

**Table 35. SAMPLES\_FOR\_AVG Register**

| AVGN | N=2 <sup>AVGN</sup> averages | Averaging/Register Update Period (ms) |
|------|------------------------------|---------------------------------------|
| 0000 | 1                            | 1                                     |
| 0001 | 2                            | 2                                     |
| 0010 | 4                            | 4                                     |
| 0011 | 8                            | 8                                     |
| 0100 | 16                           | 16                                    |
| 0101 | 32                           | 32                                    |
| 0110 | 64                           | 64                                    |
| 0111 | 128                          | 128                                   |
| 1000 | 256                          | 256                                   |
| 1001 | 512                          | 512                                   |
| 1010 | 1024                         | 1024                                  |
| 1011 | 2048                         | 2048                                  |
| 1100 | 4096                         | 4096                                  |

Note that a change in the SAMPLES\_FOR\_AVG register will not be reflected in the average telemetry measurements until the present averaging interval has completed. The default setting for AVGN is 0000 and therefore the average telemetry will mirror the instantaneous telemetry until a value higher than zero is programmed.

The SAMPLES\_FOR\_AVG register is accessed via the PMBus™ read / write byte protocol.

**Table 36. SAMPLES\_FOR\_AVG Register**

| Value    | Meaning                                               | Default |
|----------|-------------------------------------------------------|---------|
| 0h – 0Ch | Exponent (AVGN) for number of samples to average over | 00h     |

**MFR\_SPECIFIC\_12: READ\_AVG\_VIN (DCh)**

The READ\_AVG\_VIN command will report the 12-bit ADC measured input average voltage. If the data is not ready, the returned value will be the previous averaged data. However, if there is no previously averaged data, the default value (0000h) will be returned. This data is read with the PMBus™ Read Word protocol. This register should use the coefficients shown in [Table 44](#).

**Table 37. READ\_AVG\_VIN Register**

| Value      | Meaning                                      | Default |
|------------|----------------------------------------------|---------|
| 0h – 0FFFh | Average of measured values for input voltage | 0000h   |

**MFR\_SPECIFIC\_13: READ\_AVG\_VOUT (DDh)**

The READ\_AVG\_VOUT command will report the 12-bit ADC measured average output voltage. The returned value will be the default value (0000h) or previous data when the average data is not ready. This data is read with the PMBus™ Read Word protocol. This register should use the coefficients shown in [Table 44](#).

**Table 38. READ\_AVG\_VOUT Register**

| Value      | Meaning                                       | Default |
|------------|-----------------------------------------------|---------|
| 0h – 0FFFh | Average of measured values for output voltage | 0000h   |

**MFR\_SPECIFIC\_14: READ\_AVG\_IIN (DEh)**

The READ\_AVG\_IIN command will report the 12-bit ADC measured current sense average voltage. The returned value will be the default value (0000h) or previous data when the average data is not ready. This data is read with the PMBus™ Read Word protocol. This register should use the coefficients shown in [Table 44](#).

**Table 39. READ\_AVG\_IIN Register**

| Value      | Meaning                                              | Default |
|------------|------------------------------------------------------|---------|
| 0h – 0FFFh | Average of measured values for current sense voltage | 0000h   |

**MFR\_SPECIFIC\_15: READ\_AVG\_PIN (DFh)**

The READ\_AVG\_PIN command will report the upper 12 bits of the average VIN x IIN product as measured by the 12-bit ADC. You will read the default value (0000h) or previous data when the average data is not ready. This data is read with the PMBus™ Read Word protocol. This register should use the coefficients shown in [Table 44](#).

**Table 40. READ\_AVG\_PIN Register**

| Value      | Meaning                                                                   | Default |
|------------|---------------------------------------------------------------------------|---------|
| 0h – 0FFFh | Average of measured value for input voltage x input current sense voltage | 0000h   |

**MFR\_SPECIFIC\_16: BLACK\_BOX\_READ (E0h)**

The BLACK\_BOX\_READ command retrieves the BLOCK\_READ data which was latched in at the first assertion of SMBA. It is re-armed with the CLEAR\_FAULTS command. It is the same format as the BLOCK\_READ registers, the only difference being that its contents are updated with the SMBA edge rather than the internal clock edge. This command is read with the PMBus™ Block Read protocol.

**MFR\_SPECIFIC\_17: READ\_DIAGNOSTIC\_WORD (E1h)**

The READ\_DIAGNOSTIC\_WORD PMBus command will report all of the LM25066I/A faults and warnings in a single read operation. The standard response to the assertion of the SMBA signal of issuing multiple read requests to various status registers can be replaced by a single word read to the DIAGNOSTIC\_WORD register. The READ\_DIAGNOSTIC\_WORD command should be read with the PMBus™ Read Word protocol. The DIAGNOSTIC\_WORD is also returned in the BLOCK\_READ, BLACK\_BOX\_READ, and AVG\_BLOCK\_READ operations.

**Table 41. READ\_DIAGNOSTIC\_WORD Format**

| Bit | Meaning                | Default |
|-----|------------------------|---------|
| 15  | VOUT_UNDERVOLTAGE_WARN | 0       |
| 14  | IIN_OP_WARN            | 0       |
| 13  | VIN_UNDERVOLTAGE_WARN  | 0       |
| 12  | VIN_OVERVOLTAGE_WARN   | 0       |
| 11  | POWER_GOOD             | 1       |
| 10  | OVER_TEMPERATURE_WARN  | 0       |

**Table 41. READ\_DIAGNOSTIC\_WORD Format (continued)**

| Bit | Meaning                | Default |
|-----|------------------------|---------|
| 9   | TIMER_LATCHED_OFF      | 0       |
| 8   | EXT_MOSFET_SHORTED     | 0       |
| 7   | CONFIG_PRESET          | 1       |
| 6   | DEVICE_OFF             | 1       |
| 5   | VIN_UNDERVOLTAGE_FAULT | 1       |
| 4   | VIN_OVERVOLTAGE_FAULT  | 0       |
| 3   | IIN_OC/PFET_OP_FAULT   | 0       |
| 2   | OVER_TEMPERATURE_FAULT | 0       |
| 1   | CML_FAULT              | 0       |
| 0   | CIRCUIT_BREAKER_FAULT  | 0       |

**MFR\_SPECIFIC\_18: AVG\_BLOCK\_READ (E2h)**

The AVG\_BLOCK\_READ command concatenates the DIAGNOSTIC\_WORD with input and output average telemetry information (IIN, VOUT, VIN, PIN) as well as TEMPERATURE to capture all of the operating information of the part in a single PMBus™ transaction. The block is 12 bytes long with telemetry information being sent out in the same manner as if an individual READ\_AVG\_XXX command had been issued (shown below). AVG\_BLOCK\_READ also specifies that the VIN, VOUT, PIN, and IIN measurements are all time-aligned whereas there is a chance they may not be if read with individual PMBus™ commands. To read data from the AVG\_BLOCK\_READ command, use the SMBus Block Read protocol.

**Table 42. AVG\_BLOCK\_READ Register Format**

|                        |          |
|------------------------|----------|
| Byte Count (always 12) | (1 byte) |
| DIAGNOSTIC_WORD        | (1 word) |
| AVG_IIN                | (1 word) |
| AVG_VOUT               | (1 word) |
| AVG_VIN                | (1 word) |
| AVG_PIN                | (1 word) |
| TEMPERATURE            | (1 word) |

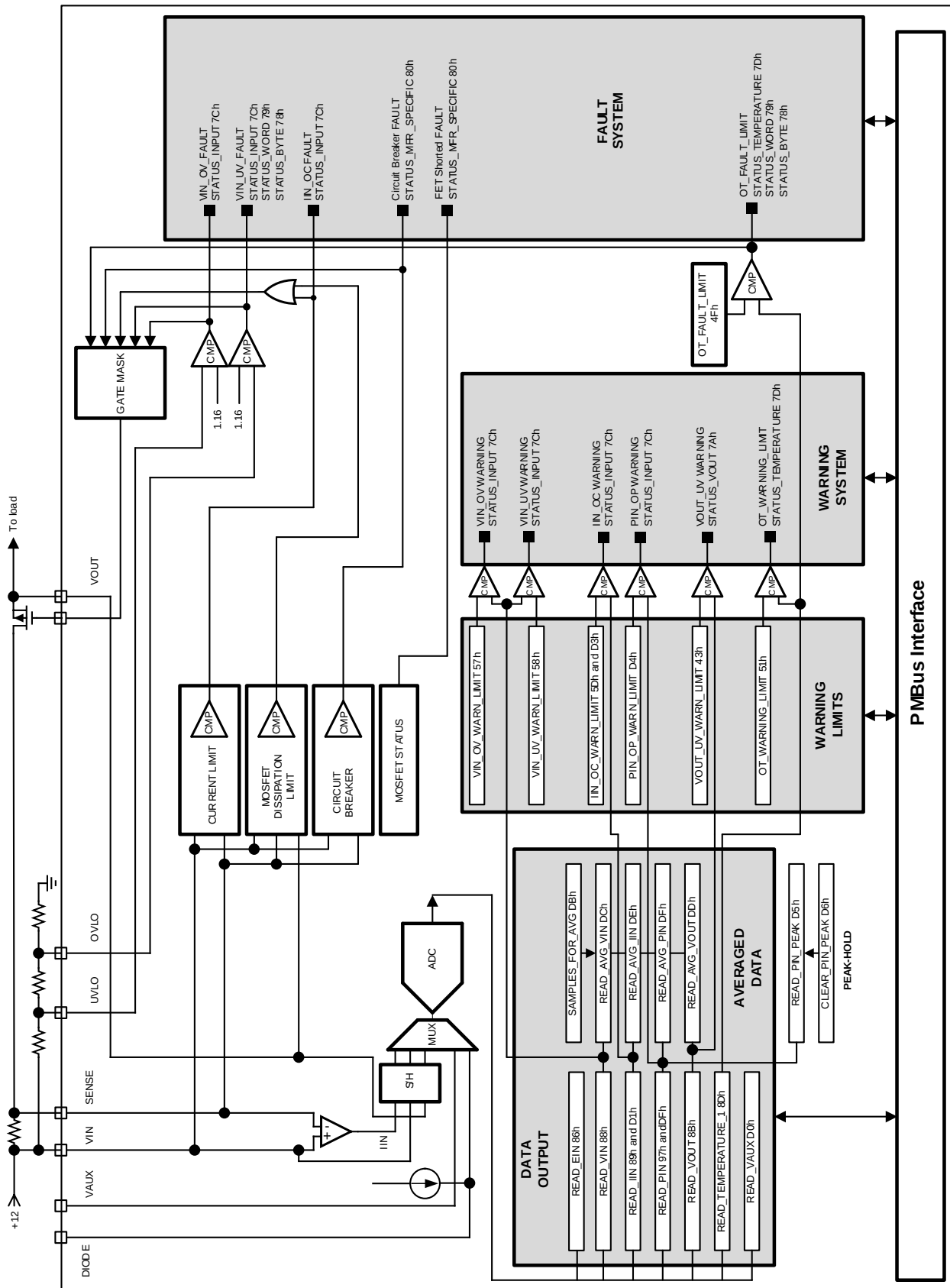


Figure 49. Command/Register and Alert Flow Diagram

## Reading and Writing Telemetry Data and Warning Thresholds

All measured telemetry data and user programmed warning thresholds are communicated in 12 bit two's complement binary numbers read/written in 2 byte increments conforming to the Direct format as described in section 8.3.3 of the PMBus™ Power System Management Protocol Specification 1.1 (Part II). The organization of the bits in the telemetry or warning word is shown in [Table 43](#), where Bit\_11 is the most significant bit (MSB) and Bit\_0 is the least significant bit (LSB). The decimal equivalent of all warning and telemetry words are constrained to be within the range of 0 to 4095, with the exception of temperature. The decimal equivalent value of the temperature word ranges from 0 to 65535.

**Table 43. Telemetry and Warning Word Format**

| Byte | B7    | B6    | B5    | B4    | B3     | B2     | B1    | B0    |
|------|-------|-------|-------|-------|--------|--------|-------|-------|
| 1    | Bit_7 | Bit_6 | Bit_5 | Bit_4 | Bit_3  | Bit_2  | Bit_1 | Bit_0 |
| 2    | 0     | 0     | 0     | 0     | Bit_11 | Bit_10 | Bit_9 | Bit_8 |

Conversion from direct format to real world dimensions of current, voltage, power, and temperature is accomplished by determining appropriate coefficients as described in section 7.2.1 of the PMBus™ Power System Management Protocol Specification 1.1 (Part II). According to this specification, the host system converts the values received into a reading of volts, amperes, watts, or other units using the following relationship:

$$X = \frac{1}{m} (Y \times 10^R - b) \quad (38)$$

where:

**X:** the calculated "real world" value (volts, amps, watt, etc.)

**m:** the slope coefficient

**Y:** a two byte two's complement integer received from device

**b:** the offset, a two byte two's complement integer

**R:** the exponent, a one byte two's complement integer

R is only necessary in systems where m is required to be an integer (for example, where m may be stored in a register in an integrated circuit). In those cases, R only needs to be large enough to yield the desired accuracy.

**Table 44. Current, Power and Warning Conversion Coefficients (R<sub>S</sub> in mΩ)**

| Commands                                                          | Condition | Format | Number of Data Bytes | m                      | b     | R  | Unit |
|-------------------------------------------------------------------|-----------|--------|----------------------|------------------------|-------|----|------|
| READ_VIN, READ_AVG_VIN<br>VIN_OV_WARN_LIMIT<br>VIN_UV_WARN_LIMIT  |           | DIRECT | 2                    | 22070                  | -1800 | -2 | V    |
| READ_VOUT, READ_AVG_VOUT<br>VOUT_UV_WARN_LIMIT                    |           | DIRECT | 2                    | 22070                  | -1800 | -2 | V    |
| READ_VAUX                                                         |           | DIRECT | 2                    | 3546                   | -3    | 0  | V    |
| READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = GND  | DIRECT | 2                    | 13661 × R <sub>S</sub> | -5200 | -2 | A    |
| READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = VDD  | DIRECT | 2                    | 6854 × R <sub>S</sub>  | -3100 | -2 | A    |
| READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = GND  | DIRECT | 2                    | 736 × R <sub>S</sub>   | -3300 | -2 | W    |
| READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = VDD  | DIRECT | 2                    | 369 × R <sub>S</sub>   | -1900 | -2 | W    |
| READ_TEMPERATURE_1<br>OT_WARN_LIMIT<br>OT_FAULT_LIMIT             |           | DIRECT | 2                    | 16000                  | 0     | -3 | °C   |
| READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = VDD  | DIRECT | 2                    | 369 × R <sub>S</sub>   | -1900 | -2 | W    |

**Table 45. Current, Power and Warning Conversion Coefficients ( $R_S$  in  $m\Omega$ )**

| Commands                                                           | Condition | Format | Number of Data Bytes | m                  | b     | R  | Unit |
|--------------------------------------------------------------------|-----------|--------|----------------------|--------------------|-------|----|------|
| *READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = GND  | DIRECT | 2                    | $13661 \times R_S$ | -5200 | -2 | A    |
| *READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = VDD  | DIRECT | 2                    | $6854 \times R_S$  | -3100 | -2 | A    |
| *READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = GND  | DIRECT | 2                    | $736 \times R_S$   | -3300 | -2 | W    |

Care must be taken to adjust the exponent coefficient, R, such that the value of m remains within the range of -32768 to +32767. For example, if a 5  $m\Omega$  sense resistor is used, the correct coefficients for the READ\_IIN command with CL = VDD would be m = 6830, b = -310, R = -1.

### A Note on the "b" Coefficient

Since b coefficients represent offset, for simplification b is set to zero in the following discussions.

### Determining Telemetry Coefficients Empirically with Linear Fit

The coefficients for telemetry measurements and warning thresholds presented in Table 44 are adequate for the majority of applications. Current and power coefficients must be calculated per application as they are dependent on the value of the sense resistor,  $R_S$ , used. Table 45 provides the equations necessary for calculating the current and power coefficients for the general case. The small signal nature of the current measurement make it and the power measurement more susceptible to PCB parasitics than other telemetry channels. This may cause slight variations in the optimum coefficients (m, b, R) for converting from Direct Format digital values to real-world values (e.g. Amps and Watts). The optimum coefficients can be determined empirically for a specific application and PCB layout using two or more measurements of the telemetry channel of interest. The current coefficients can be determined using the following method:

1. While the LM25066I/A is in normal operation, measure the voltage across the sense resistor using kelvin test points and a high accuracy DVM while controlling the load current. Record the integer value returned by the READ\_AVG\_IIN command (with the SAMPLES\_FOR\_AVG set to a value greater than 0) for two or more voltages across the sense resistor. For best results, the individual READ\_AVG\_IIN measurements should span nearly the full scale range of the current (for example, voltage across  $R_S$  of 5 mV and 20 mV).
2. Convert the measured voltages to currents by dividing them by the value of  $R_S$ . For best accuracy, the value of  $R_S$  should be measured. Table 46 assumes a sense resistor value of 5  $m\Omega$ .

**Table 46. Measurements for linear fit determination of current coefficients**

| Measured voltage across $R_S$ (V) | Measured Current (A) | READ_AVG_IIN (integer value) |
|-----------------------------------|----------------------|------------------------------|
| 0.005                             | 1                    | 648                          |
| 0.01                              | 2                    | 1331                         |
| 0.02                              | 4                    | 2698                         |

3. Using the spreadsheet or math program of your choice, determine the slope and the y-intercept values returned by the READ\_AVG\_IIN command versus the measured current. For the data shown in Table 46:
  - READ\_AVG\_IIN value = slope x (Measured Current) + (y-intercept)
  - slope = 683.4
  - y-intercept = -35.5
4. To determine the 'm' coefficient, simply shift the decimal point of the calculated slope to arrive at an integer with a suitable number of significant digits for accuracy (typically 4) while staying with the range of -32768 to +32767. This shift in the decimal point equates to the 'R' coefficient. For the slope value shown above, the decimal point would be shifted to the right once hence **R** = -1.
5. Once the 'R' coefficient has been determined, the 'b' coefficient is found by multiplying the y-intercept by  $10^R$ . In this case the value of **b** = -355.
  - Calculated Current Coefficients:
  - **m** = 6834

$$- \mathbf{b} = -355$$

$$- \mathbf{R} = -1$$

$$\mathbf{X} = \frac{1}{\mathbf{m}} (\mathbf{Y} \times 10^{\mathbf{R}} - \mathbf{b})$$

(39)

where:

**X**: the calculated "real world" value (volts, amps, watts, temperature)

**m**: the slope coefficient, a the two byte two's complement integer

**Y**: a two byte, two's complement integer received from device

**b**: the offset, a two byte two's complement integer

**R**: the exponent, a one byte two's complement integer

The above procedure can be repeated to determine the coefficients of any telemetry channel simply by substituting measured current for some other parameter (e.g. power, voltage, etc.).

## Writing Telemetry Data

There are several locations that will require writing data if their optional usage is desired. Use the same coefficients previously calculated for your application and apply them using this method as prescribed by the PMBus™ revision section 7.2.2 "Sending a Value"

$$\mathbf{Y} = (\mathbf{mX} + \mathbf{b}) \times 10^{\mathbf{R}}$$

(40)

where:

**X**: the calculated "real world" value (volts, amps, watts, temperature)

**m**: the slope coefficient, a two byte two's complement integer

**Y**: a two byte two's complement integer received from device

**b**: the offset, a two byte two's complement integer

**R**: the exponent, a one byte two's complement integer

## PMBus™ Address Lines (ADR0, ADR1, ADR2)

The three address lines are to be set high (connect to VDD), low (connect to GND), open (connect to GND) to select one of 27 addresses for communicating with the LM25066I/A. [Table 47](#) depicts 7-bit addresses (eighth bit is read/write bit):

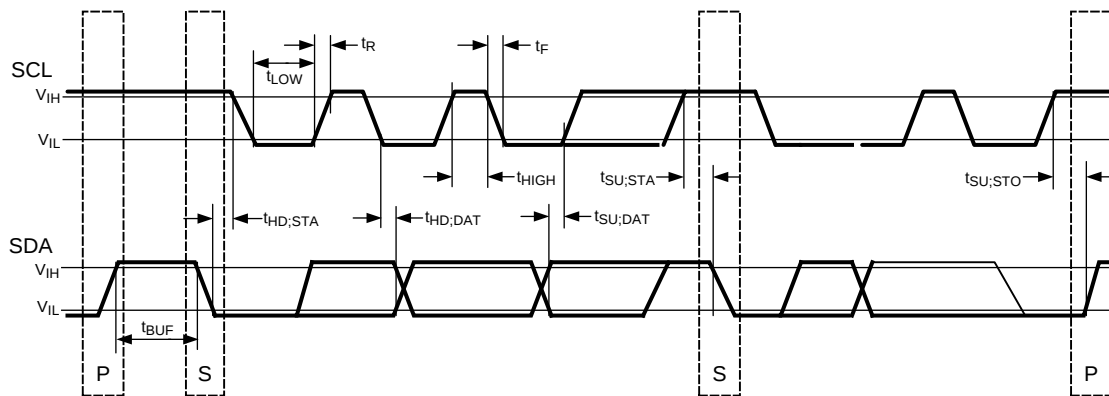
**Table 47. Device Addressing**

| ADR2 | ADR1 | ADR0 | Decoded Address |
|------|------|------|-----------------|
| Z    | Z    | Z    | 40h             |
| Z    | Z    | 0    | 41h             |
| Z    | Z    | 1    | 42h             |
| Z    | 0    | Z    | 43h             |
| Z    | 0    | 0    | 44h             |
| Z    | 0    | 1    | 45h             |
| Z    | 1    | Z    | 46h             |
| Z    | 1    | 0    | 47h             |
| Z    | 1    | 1    | 10h             |
| 0    | Z    | Z    | 11h             |
| 0    | Z    | 0    | 12h             |
| 0    | Z    | 1    | 13h             |
| 0    | 0    | Z    | 14h             |
| 0    | 0    | 0    | 15h             |
| 0    | 0    | 1    | 16h             |

**Table 47. Device Addressing (continued)**

| ADR2 | ADR1 | ADR0 | Decoded Address |
|------|------|------|-----------------|
| 0    | 1    | Z    | 17h             |
| 0    | 1    | 0    | 50h             |
| 0    | 1    | 1    | 51h             |
| 1    | Z    | Z    | 52h             |
| 1    | Z    | 0    | 53h             |
| 1    | Z    | 1    | 54h             |
| 1    | 0    | Z    | 55h             |
| 1    | 0    | 0    | 56h             |
| 1    | 0    | 1    | 57h             |
| 1    | 1    | Z    | 58h             |
| 1    | 1    | 0    | 59h             |
| 1    | 1    | 1    | 5Ah             |

## SMBus Communications Timing Requirements


**Figure 50. SMBus Timing Diagram**
**Table 48. SMBus Timing Definition**

| Symbol        | Parameter                                                                                    | Limits |     | Unit    | Comments |
|---------------|----------------------------------------------------------------------------------------------|--------|-----|---------|----------|
|               |                                                                                              | Min    | Max |         |          |
| $F_{SMB}$     | SMBus Operating Frequency                                                                    | 10     | 400 | kHz     |          |
| $T_{BUF}$     | Bus free time between Stop and Start Condition                                               | 1.3    |     | $\mu s$ |          |
| $T_{HD;STA}$  | Hold time after (Repeated) Start Condition. After this period, the first clock is generated. | 0.6    |     | $\mu s$ |          |
| $T_{SU;STA}$  | Repeated Start Condition setup time                                                          | 0.6    |     | $\mu s$ |          |
| $T_{SU;STO}$  | Stop Condition setup time                                                                    | 0.6    |     | $\mu s$ |          |
| $T_{HD;DAT}$  | Data hold time                                                                               | 300    |     | ns      |          |
| $T_{SU;DAT}$  | Data setup time                                                                              | 100    |     | ns      |          |
| $T_{TIMEOUT}$ | Clock low time-out                                                                           | 25     | 35  | ms      | (1)      |
| $T_{LOW}$     | Clock low period                                                                             | 1.5    |     | $\mu s$ |          |
| $T_{HIGH}$    | Clock high period                                                                            | 0.6    |     | $\mu s$ | (2)      |

- (1) Devices participating in a transfer will timeout when any clock low exceeds the value of  $T_{TIMEOUT,MIN}$  of 25 ms. Devices that have detected a timeout condition must reset the communication no later than  $T_{TIMEOUT,MAX}$  of 35 ms. The maximum value must be adhered to by both a master and a slave as it incorporates the cumulative stretch limit for both a master (10ms) and a slave (25ms).
- (2)  $T_{HIGH,MAX}$  provides a simple method for devices to detect bus idle conditions.

**Table 48. SMBus Timing Definition (continued)**

| Symbol                | Parameter                                       | Limits |     | Unit | Comments |
|-----------------------|-------------------------------------------------|--------|-----|------|----------|
|                       |                                                 | Min    | Max |      |          |
| $T_{\text{LOW:SEXT}}$ | Cumulative clock low extend time (slave device) |        | 25  | ms   | (3)      |
| $T_{\text{LOW:MEXT}}$ | Cumulative low extend time (master device)      |        | 10  | ms   | (4)      |
| $T_F$                 | Clock or Data Fall Time                         | 20     | 300 | ns   | (5)      |
| $T_R$                 | Clock or Data Rise Time                         | 20     | 300 | ns   | (5)      |

- (3)  $T_{\text{LOW:SEXT}}$  is the cumulative time a slave device is allowed to extend the clock cycles in one message from the initial start to the stop. If a slave exceeds this time, it is expected to release both its clock and data lines and reset itself.
- (4)  $T_{\text{LOW:MEXT}}$  is the cumulative time a master device is allowed to extend its clock cycles within each byte of a message as defined from start-to-ack, ack-to-ack, or ack-to-stop.
- (5) Rise and fall time is defined as follows: •  $T_R = (V_{\text{ILMAX}} - 0.15) \text{ to } (V_{\text{IHMIN}} + 0.15)$  •  $T_F = 0.9 \text{ VDD to } (V_{\text{ILMAX}} - 0.15)$

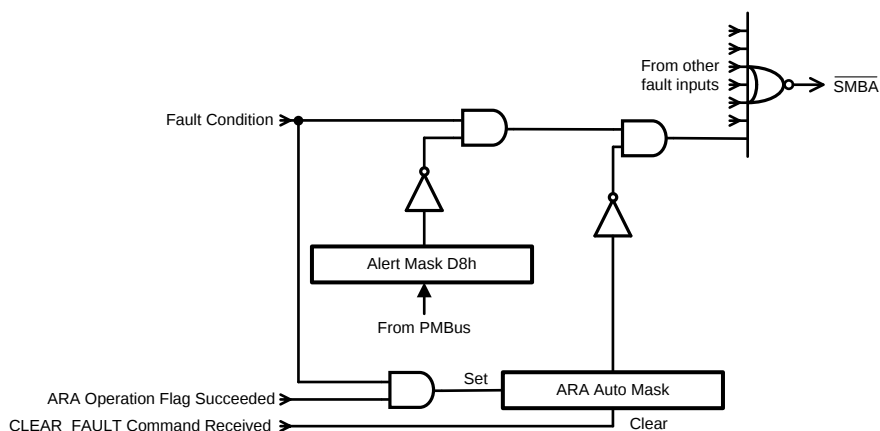
## SMBA Response

The  $\overline{\text{SMBA}}$  effectively has two masks:

1. The Alert Mask Register at D8h, and
2. The ARA Automatic Mask.

The ARA Automatic Mask is a mask that is set in response to a successful ARA read. An ARA read operation returns the PMBus™ address of the lowest addressed part on the bus that has its  $\overline{\text{SMBA}}$  asserted. A successful ARA read means that THIS part was the one that returned its address. When a part responds to the ARA read, it releases the  $\overline{\text{SMBA}}$  signal. When the last part on the bus that has an  $\overline{\text{SMBA}}$  set has successfully reported its address, the  $\overline{\text{SMBA}}$  signal will de-assert.

The way that the LM25066I/A releases the  $\overline{\text{SMBA}}$  signal is by setting the ARA Automatic mask bit for all fault conditions present at the time of the ARA read. All status registers will still show the fault condition, but it will not generate an  $\overline{\text{SMBA}}$  on that fault again until the ARA Automatic mask is cleared by the host issuing a Clear Fault command to this part. This should be done as a routine part of servicing an  $\overline{\text{SMBA}}$  condition on a part, even if the ARA read is not done. Figure 51 depicts a schematic version of this flow.

**Figure 51. Typical Flow Schematic for  $\overline{\text{SMBA}}$  Fault**

## REVISION HISTORY

### Changes from Revision B (March 2013) to Revision C

**Page**

- Changed layout of National Data Sheet to TI format ..... [52](#)

## PACKAGING INFORMATION

| Orderable Device   | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|--------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| LM25066IAPSQ/NOPB  | ACTIVE        | WQFN         | NHZ                | 24   | 1000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-3-260C-168 HR  | -40 to 125   | 25066IA                 | <a href="#">Samples</a> |
| LM25066IAPSQE/NOPB | ACTIVE        | WQFN         | NHZ                | 24   | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-3-260C-168 HR  | -40 to 125   | 25066IA                 | <a href="#">Samples</a> |
| LM25066IAPSQX/NOPB | ACTIVE        | WQFN         | NHZ                | 24   | 4500           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-3-260C-168 HR  | -40 to 125   | 25066IA                 | <a href="#">Samples</a> |
| LM25066IPSQ/NOPB   | ACTIVE        | WQFN         | NHZ                | 24   | 1000           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-3-260C-168 HR  | -40 to 125   | 25066IS                 | <a href="#">Samples</a> |
| LM25066IPSQE/NOPB  | ACTIVE        | WQFN         | NHZ                | 24   | 250            | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-3-260C-168 HR  | -40 to 125   | 25066IS                 | <a href="#">Samples</a> |
| LM25066IPSQX/NOPB  | ACTIVE        | WQFN         | NHZ                | 24   | 4500           | Green (RoHS<br>& no Sb/Br) | CU SN                   | Level-3-260C-168 HR  | -40 to 125   | 25066IS                 | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

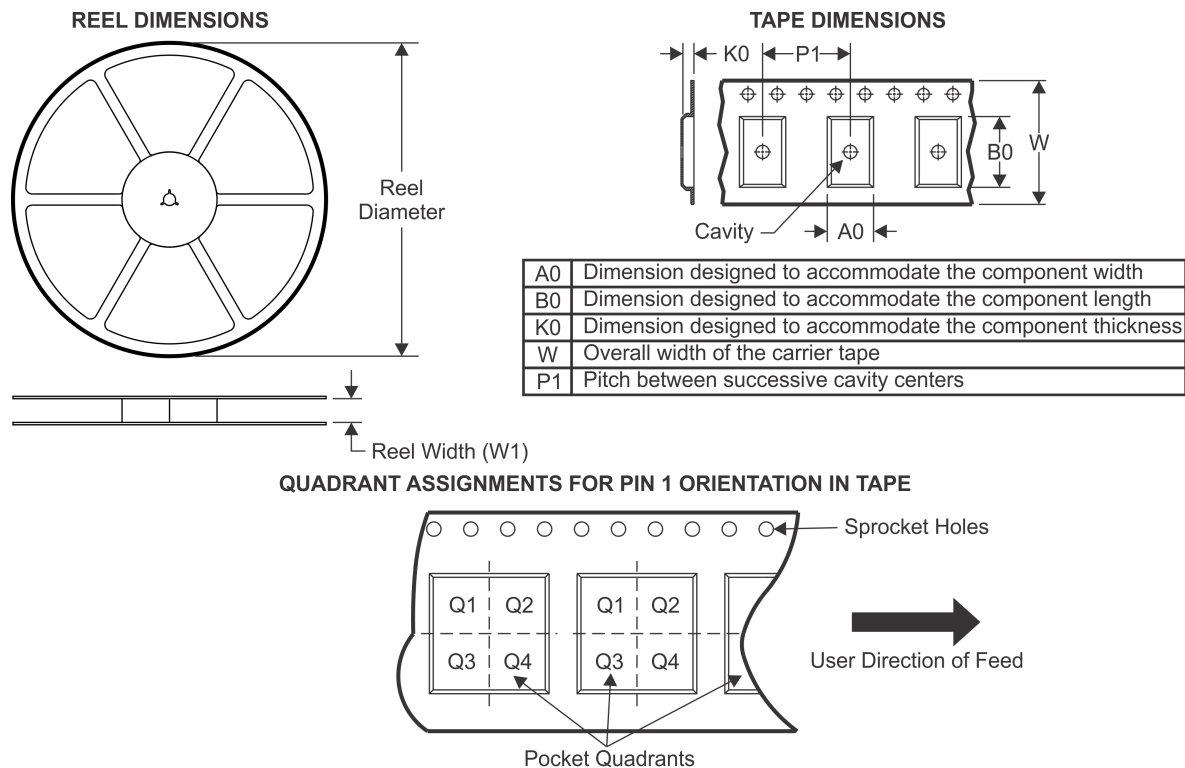
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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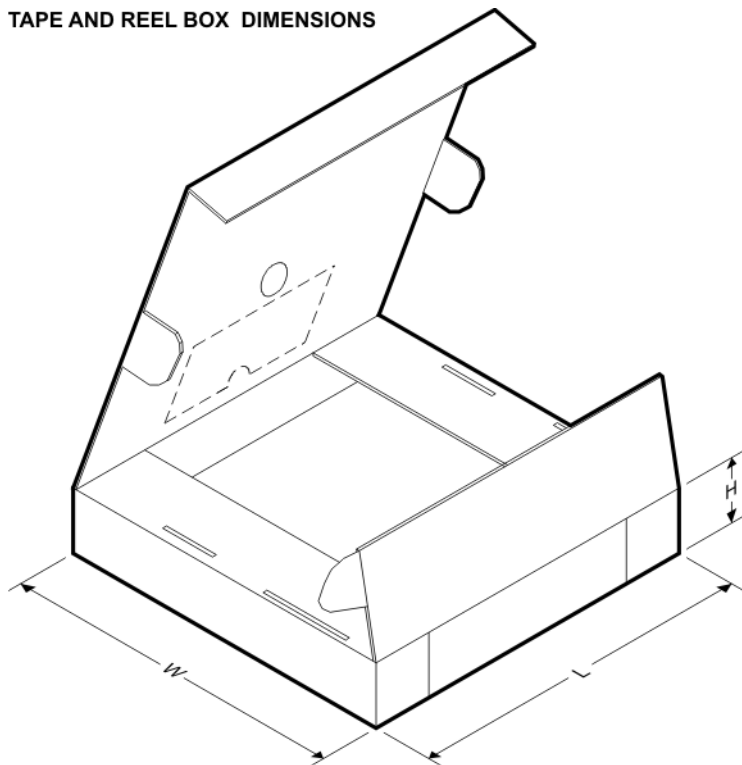
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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device             | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM25066IAPSQ/NOPB  | WQFN         | NHZ             | 24   | 1000 | 178.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |
| LM25066IAPSQE/NOPB | WQFN         | NHZ             | 24   | 250  | 178.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |
| LM25066IAPSQX/NOPB | WQFN         | NHZ             | 24   | 4500 | 330.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |
| LM25066IPSQ/NOPB   | WQFN         | NHZ             | 24   | 1000 | 178.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |
| LM25066IPSQE/NOPB  | WQFN         | NHZ             | 24   | 250  | 178.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |
| LM25066IPSQX/NOPB  | WQFN         | NHZ             | 24   | 4500 | 330.0              | 12.4               | 4.3     | 5.3     | 1.3     | 8.0     | 12.0   | Q1            |

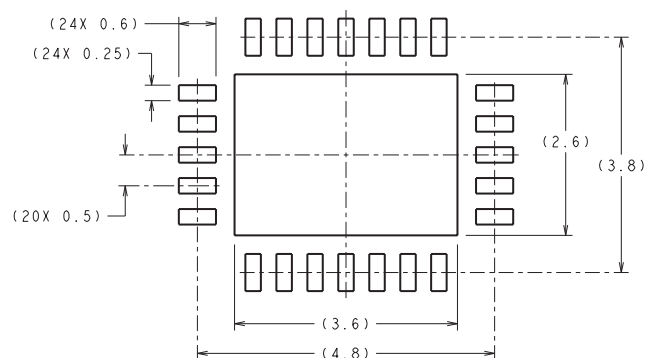
## TAPE AND REEL BOX DIMENSIONS



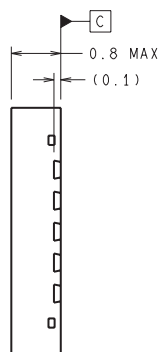
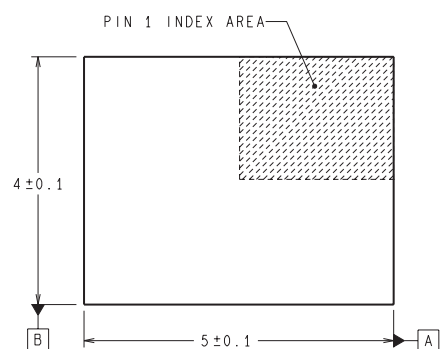
\*All dimensions are nominal

| Device             | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM25066IAPSQ/NOPB  | WQFN         | NHZ             | 24   | 1000 | 213.0       | 191.0      | 55.0        |
| LM25066IAPSQE/NOPB | WQFN         | NHZ             | 24   | 250  | 213.0       | 191.0      | 55.0        |
| LM25066IAPSQX/NOPB | WQFN         | NHZ             | 24   | 4500 | 367.0       | 367.0      | 35.0        |
| LM25066IPSQ/NOPB   | WQFN         | NHZ             | 24   | 1000 | 213.0       | 191.0      | 55.0        |
| LM25066IPSQE/NOPB  | WQFN         | NHZ             | 24   | 250  | 213.0       | 191.0      | 55.0        |
| LM25066IPSQX/NOPB  | WQFN         | NHZ             | 24   | 4500 | 367.0       | 367.0      | 35.0        |

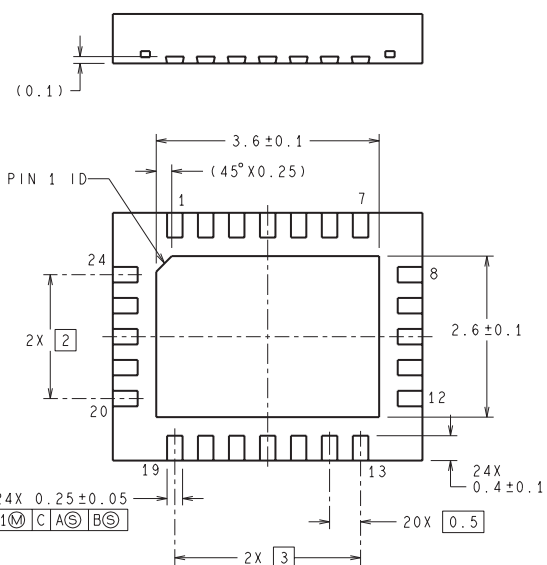
NHZ0024B



RECOMMENDED LAND PATTERN



**DIMENSIONS ARE IN MILLIMETERS**  
 DIMENSIONS IN ( ) FOR REFERENCE ONLY



SQA24B (Rev A)

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|                               |                                                                                          |
|-------------------------------|------------------------------------------------------------------------------------------|
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